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Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



Includes
FLEX 8000A

FLEX 8000

Programmable Logic
Device Family

August 1994, ver. 4

Data Sheet

Features

- High-density, register-rich programmable logic device family
 - 2,500 to 16,000 usable gates
 - 282 to 1,500 registers
- FLEX 8000 devices fabricated on 0.8-micron CMOS SRAM technology
- Higher-speed FLEX 8000A devices fabricated on a 0.65-micron CMOS SRAM technology
- In-circuit reconfigurable
- FastTrack continuous routing structure for fast, predictable interconnect delays
- Dedicated carry chain that can implement fast adders and counters
- Dedicated cascade chain for efficient implementation of high-speed, high-fan-in logic functions
- Programmable output slew-rate control to reduce switching noise
- Full PCI-bus specification compliance for FLEX 8000A devices
- Built-in Joint Test Action Group (JTAG) Boundary-Scan test circuitry
- 3.3- or 5.0-V operation
 - Full 3.3-V EPF8282V
 - 3.3- or 5.0-V I/O for EPF8636A and larger devices
- Available in a variety of packages with 84 to 304 pins (see Table 1)

Table 1. FLEX 8000 Device Features

Feature	EPF8282 EPF8282V EPF8282A EPF8282AV	EPF8452 EPF8452A	EPF8636A	EPF8820 EPF8820A	EPF81188 EPF81188A	EPF81500 EPF81500A
Available Gates	5,000	8,000	12,000	16,000	24,000	32,000
Usable Gates	2,500	4,000	6,000	8,000	12,000	16,000
Flipflops	282	452	636	820	1,188	1,500
Logic Elements	208	336	504	672	1,008	1,296
Max. User I/O Pins	78	120	136	152	184	208
JTAG BST Circuitry	Yes	No	Yes	Yes	No	Yes
Packages (1)	84-pin PLCC 100-pin TQFP	84-pin PLCC 160-pin PQFP 160-pin PGA	84-pin PLCC 160-pin RQFP 192-pin PGA 208-pin RQFP	160-pin RQFP 192-pin PGA 208-pin RQFP 225-pin BGA	208-pin RQFP 232-pin PGA 240-pin RQFP	240-pin RQFP 280-pin PGA 304-pin RQFP

Note:

(1) Contact Altera for information on package availability.

ALTES007

... and More Features

- ❑ Software design support and automatic place-and-route with Altera's MAX+PLUS II development system for PC, Sun SPARCstation, HP 9000 Series 700, and DEC Alpha AXP platforms
- ❑ Low power consumption (less than 1 mA in standby mode)

General Description

Altera's Flexible Logic Element Matrix (FLEX) family combines the benefits of both EPLDs and FPGAs. The fine-grained architecture and high register count characteristic of FPGAs are combined with the high speed and predictable interconnect delays of EPLDs to make the FLEX 8000 device family ideal for a wide range of applications. Logic is implemented with compact 4-input look-up tables (LUTs) and programmable registers. High performance is provided by a fast, continuous network of routing resources.

FLEX 8000 devices provide a large number of storage elements for applications such as digital signal processing, wide data-path manipulation, and data transformation. These devices are an excellent choice for bus interfaces, TTL integration, coprocessor functions, and high-speed controllers. The high-pin-count packages can integrate multiple 32-bit buses into a single device. Table 2 shows the performance of FLEX 8000 devices as shown in benchmarks of typical applications.

Application	Logic Elements Used	FLEX 8000A Devices			FLEX 8000 Devices	
		A-3 Speed Grade	A-4 Speed Grade	A-5 Speed Grade	-2 Speed Grade	-3 Speed Grade
16-bit loadable counter	16	95 MHz	83 MHz	71 MHz	71 MHz	45 MHz
16-bit up/down counter	16	95 MHz	83 MHz	71 MHz	71 MHz	45 MHz
16-bit prescaled counter	24	232 MHz	185 MHz	151 MHz	142 MHz	115 MHz
24-bit accumulator	24	67 MHz	58 MHz	50 MHz	50 MHz	32 MHz
16-bit address decode	4	4.9 ns	6.3 ns	7.7 ns	7.8 ns	12.0 ns
16-to-1 multiplexer	10	5.9 ns	8.1 ns	12.1 ns	12.7 ns	18.0 ns

Note:

(1) The A-6 speed grade yields the same results as the -3 speed grade.

All FLEX 8000 device packages provide four dedicated inputs for synchronous control signals with large fan-outs. Each I/O pin has an associated register on the periphery of the device. As outputs, these registers provide fast Clock-to-output times; as inputs, they offer quick setup times.

The logic and interconnections in the FLEX 8000 architecture are configured with CMOS SRAM cells. FLEX 8000 devices are configured at system power-up with data stored in a serial Configuration EPROM device or provided by a system controller. Altera offers the EPC1213 and EPC1064 Configuration EPROMs, which configure FLEX 8000 devices via a serial data stream. Configuration data can also be stored in an industry-standard $32\text{K} \times 8$ -bit or larger EPROM or downloaded from system RAM. After a FLEX 8000 device has been configured, it can be reconfigured in-circuit by resetting the device and loading new data. Because reconfiguration requires less than 100 ms, real-time changes can be made during system operation.

You can use Altera's MAX+PLUS II development system to create FLEX 8000 logic designs with any combination of graphic, text—including the Altera Hardware Description Language (AHDL), VHSIC Hardware Description Language (VHDL), and Verilog HDL—and waveform design entry. Full simulation, worst-case timing analysis, and functional testing are available for design verification. MAX+PLUS II also provides EDIF 2.0.0 and EDIF 2.9.0 netlist interfaces for additional design entry and simulation support with industry-standard CAE tools. In addition, MAX+PLUS II can export Verilog HDL and VHDL netlist files.

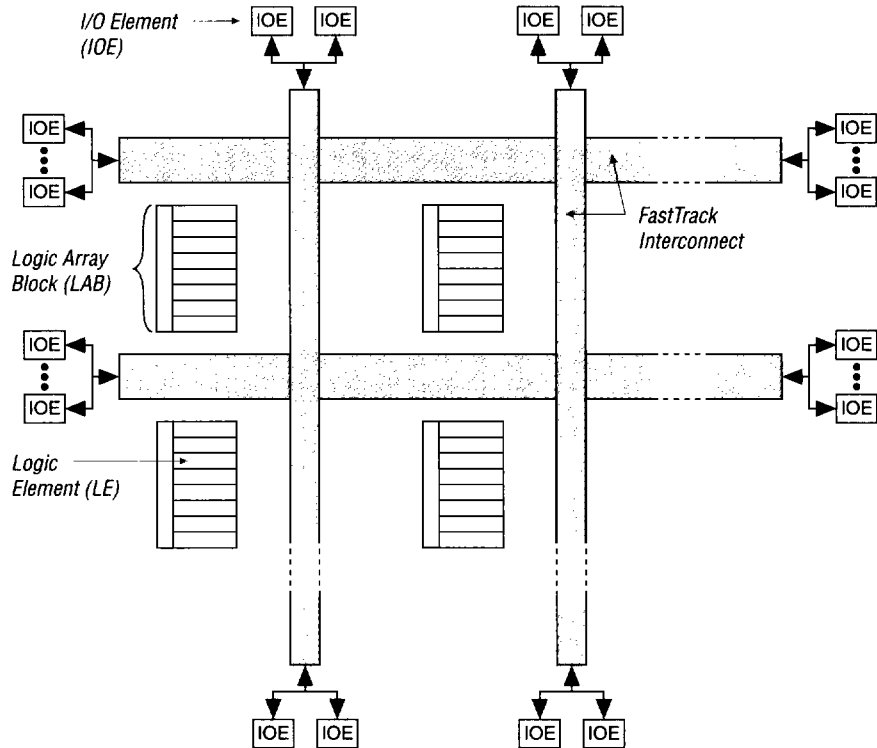
Functional Description

The FLEX 8000 architecture incorporates a large matrix of compact building blocks called logic elements (LEs). Each LE contains a 4-input LUT that provides combinatorial logic capability and a programmable register that offers sequential logic capability. The fine-grained structure of the LE provides highly efficient logic implementation.

LEs are grouped into sets of eight to create Logic Array Blocks (LABs). Each FLEX 8000 LAB is an independent structure with common inputs, interconnections, and control signals. The LAB architecture provides a coarse-grained structure for high device performance and easy routing.

Figure 1 shows a block diagram of the FLEX 8000 architecture. Each group of eight LEs is combined into an LAB; LABs are arranged into rows and columns. The I/O pins are supported by I/O elements (IOEs) located at the ends of rows and columns. Each IOE contains a bidirectional I/O buffer and a flipflop that can be used as either an input or output register.

Figure 1. FLEX 8000 Device Block Diagram

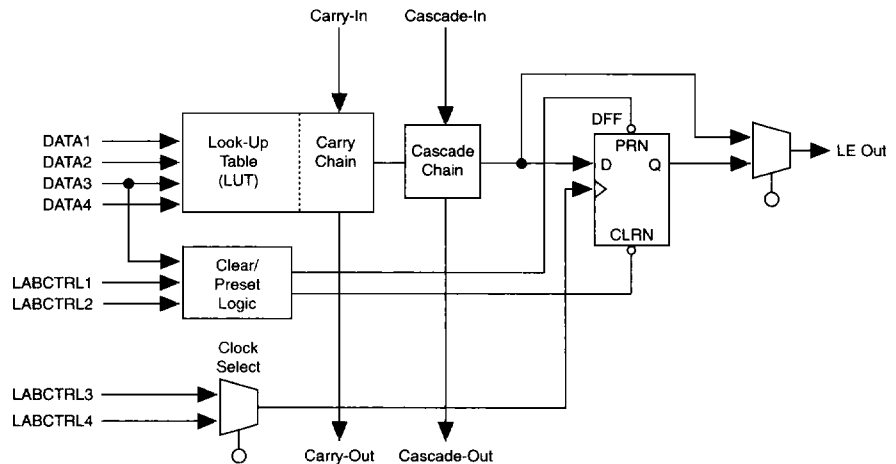


Signal interconnections within FLEX 8000 devices and to and from device pins are provided by the FastTrack Interconnect, a series of fast, continuous channels that run the entire length and width of the device. IOEs are located at the end of each row (horizontal) and column (vertical) FastTrack Interconnect path.

Logic Element

The logic element (LE) is the smallest unit of logic in the FLEX 8000 architecture, with a compact size that provides efficient logic utilization. Each LE contains a four-input LUT, a programmable flipflop, a carry chain, and a cascade chain. Figure 2 shows a block diagram of the LE.

Figure 2. FLEX 8000 Logic Element (LE)



The LUT is a function generator that can quickly compute any function of four variables. The programmable flipflop in the LE can be configured for D, T, JK, or SR operation. The Clock, Clear, and Preset control signals on the flipflop can be driven by dedicated input pins, general-purpose I/O pins, or any internal logic. For purely combinatorial functions, the flipflop is bypassed and the output of the LUT goes directly to the output of the LE.

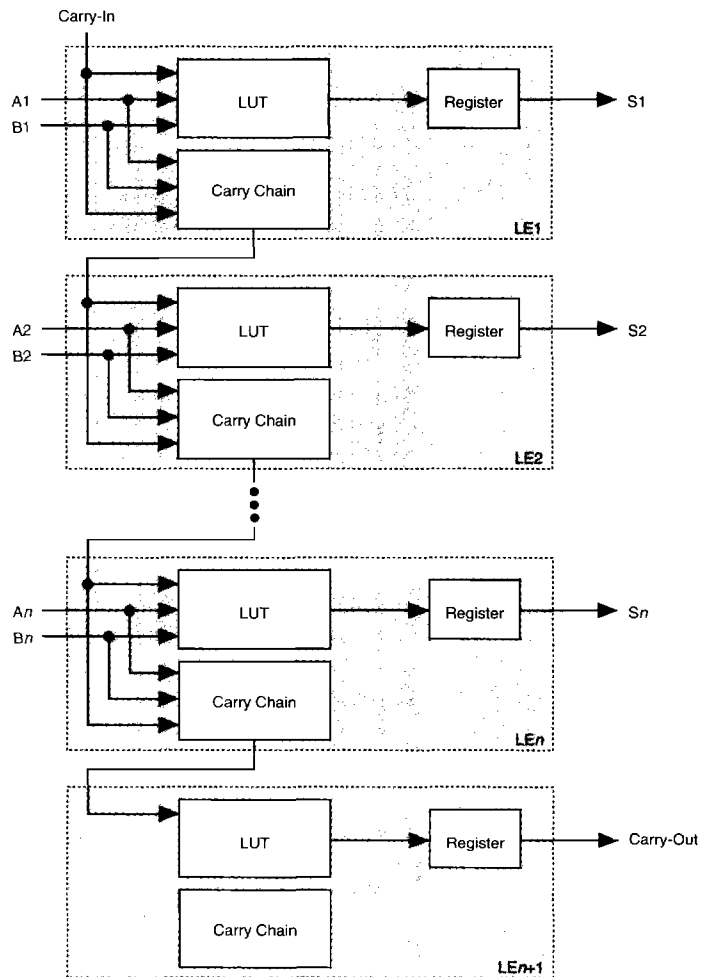
The FLEX 8000 architecture provides two dedicated high-speed data paths, carry chains and cascade chains, that connect adjacent LEs without using local interconnect paths. The carry chain supports high-speed counters and adders; the cascade chain implements wide-input functions with minimum delay. Carry and cascade chains connect all LEs in an LAB and all LABs in the same row. Heavy use of carry and cascade chains can reduce the routing resources available for implementing other logic. Therefore, the use of carry and cascade chains should be limited to speed-critical portions of a design.

Carry Chain

The carry chain provides a very fast (less than 1 ns) carry-forward function between LEs. The carry-in signal from a lower-order bit moves forward into the higher-order bit via the carry chain, and feeds into both the LUT and the next portion of the carry chain. This feature allows the FLEX 8000 architecture to implement high-speed counters and adders of arbitrary width. The MAX+PLUS II Compiler can create carry chains automatically during design processing; designers can also insert carry chain logic manually during design entry.

Figure 3 shows how an n -bit full adder can be implemented in $n+1$ LEs by using the carry chain. One portion of the LUT generates the sum of two bits using the input signals and the carry-in signal; the sum is routed to the output of the LE. The register is typically bypassed for simple adders, but can be used for an accumulator function. Another portion of the LUT and the carry chain logic generate the carry-out signal, which is routed directly to the carry-in signal of the next-higher-order bit. The final carry-out signal is routed to an LE, where it can be used as a general-purpose signal. In addition to mathematical functions, carry chain logic supports very fast counters and comparators.

Figure 3. Carry Chain Operation

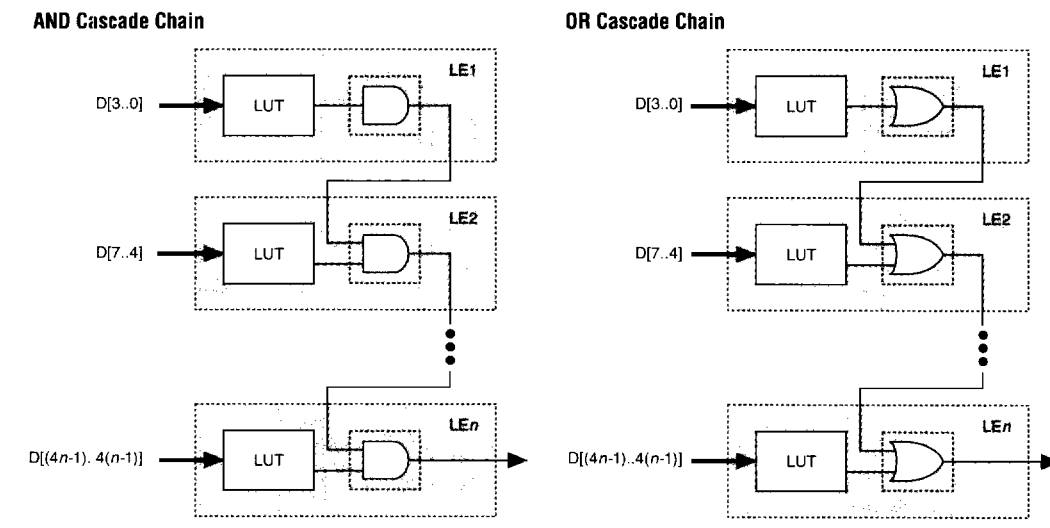


Cascade Chain

With the cascade chain, the FLEX 8000 architecture can implement functions that have a very wide fan-in. Adjacent LUTs can be used to compute portions of the function in parallel; the cascade chain serially connects the intermediate values. The cascade chain can use a logical AND or logical OR (via De Morgan's inversion) to connect the outputs of adjacent LEs. Each additional LE provides four more inputs to the effective width of a function, with a delay of approximately 1 ns per LE. The MAX+PLUS II Compiler can create cascade chains automatically during design processing; designers can also insert cascade chain logic manually during design entry.

Figure 4 shows how the cascade function can connect adjacent LEs to form functions with a wide fan-in. These examples show functions of $4n$ variables implemented with n LEs. For a device with an A-3 speed grade, the LUT delay is approximately 1.8 ns; the cascade chain delay is 0.7 ns. With the cascade chain, 5.0 ns is needed to decode a 16-bit address.

Figure 4. Cascade Chain Operation



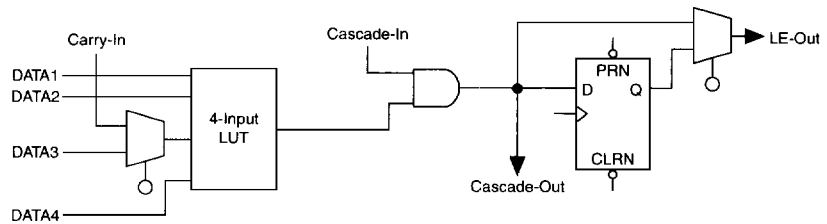
Logic Element Operating Modes

The FLEX 8000 logic element can operate in one of four modes, shown in Figure 5, each of which uses LE resources differently. In each mode, seven of the ten available inputs to the LE—the four data inputs from the LAB local interconnect, the feedback from the programmable register, and the carry-in and cascade-in from the previous LE—are directed to different

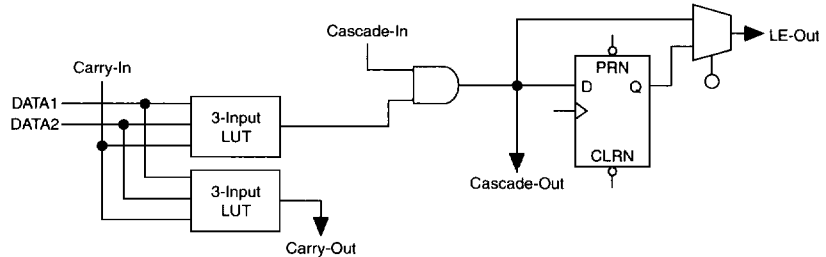
destinations to implement the desired logic function. The three remaining inputs to the LE provide Clock, Clear, and Preset control for the register. MAX+PLUS II software automatically chooses the appropriate mode for each application. Design performance can also be enhanced by designing for the operating mode that supports the desired application.

Figure 5. FLEX 8000 Logic Element Operating Modes

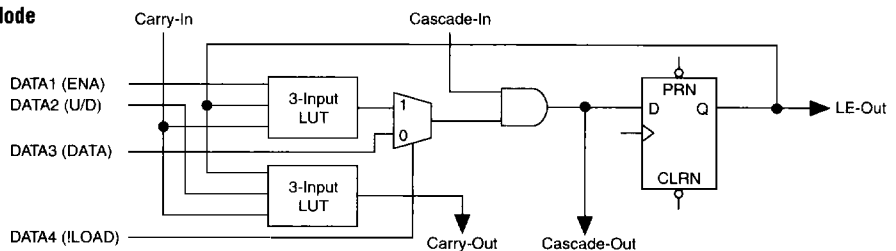
Normal Mode



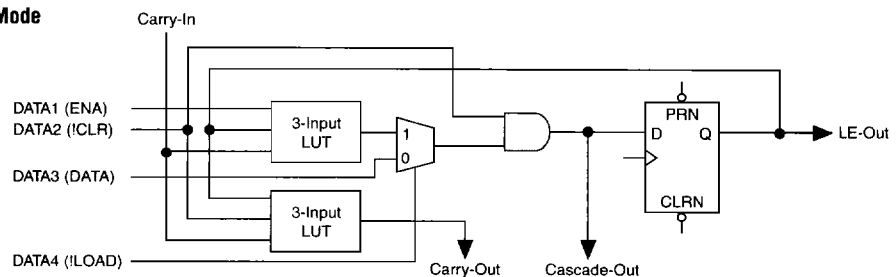
Arithmetic Mode



Up/Down Counter Mode



Clearable Counter Mode



Normal Mode

The Normal mode is suitable for general logic applications and wide decode functions that can take advantage of a cascade chain. In Normal mode, four data inputs from the LAB local interconnect and the carry-in are the inputs to a 4-input LUT. Using a configurable SRAM bit, the MAX+PLUS II Compiler automatically selects the carry-in or the DATA3 signal as an input. The LUT output can be combined with the cascade-in signal to form a cascade chain through the cascade-out signal. The LE-out signal—the data output of the LE—is either the combinatorial output of the LUT and cascade chain, or the Q output of the programmable register.

Arithmetic Mode

The Arithmetic mode offers two 3-input LUTs that are ideal for implementing adders, accumulators, and comparators. One LUT provides a 3-bit function; the other generates a carry bit. As shown in Figure 5, the first LUT uses the carry-in signal and two data inputs from the LAB local interconnect to generate a combinatorial or registered output. For example, in an adder, this output would be the sum of three bits: A, B, and carry-in. The second LUT uses the same three signals to generate a carry-out signal, thereby creating a carry chain. The Arithmetic mode also supports a cascade chain.

Up/Down Counter Mode

The Up/Down Counter mode offers counter enable, synchronous up/down control, and data loading options. These control signals are generated by the data inputs from the LAB local interconnect, the carry-in signal, and output feedback from the programmable register. Two 3-input LUTs are used: one generates the counter data, the other generates the fast carry bit. A 2-to-1 multiplexer provides synchronous loading. Data can also be loaded asynchronously with the Clear and Preset register control signals, without using the LUT resources.

Clearable Counter Mode

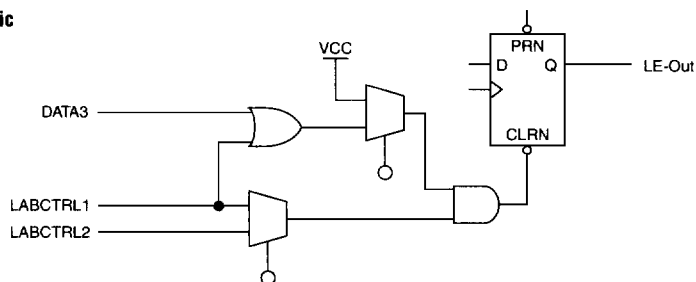
The Clearable Counter mode is similar to the Up/Down Counter mode, but supports a synchronous Clear instead of the up/down control. The Clear function is substituted for the cascade-in signal in the Up/Down Counter mode. Two 3-input LUTs are used: one generates the counter data, the other generates the fast carry bit. Synchronous loading is provided by a 2-to-1 multiplexer, the output of which is ANDed with a synchronous Clear.

Clear/Preset Logic Control

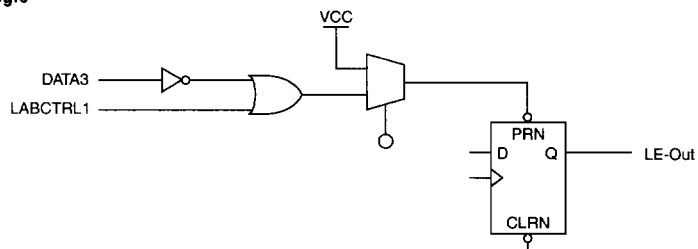
Logic for the programmable register's Clear and Preset functions is controlled by the DATA3, LABCTRL1, and LABCTRL2 inputs to the LE. See Figure 6.

Figure 6. Logic Element Clear & Preset Logic

Clear Logic



Preset Logic

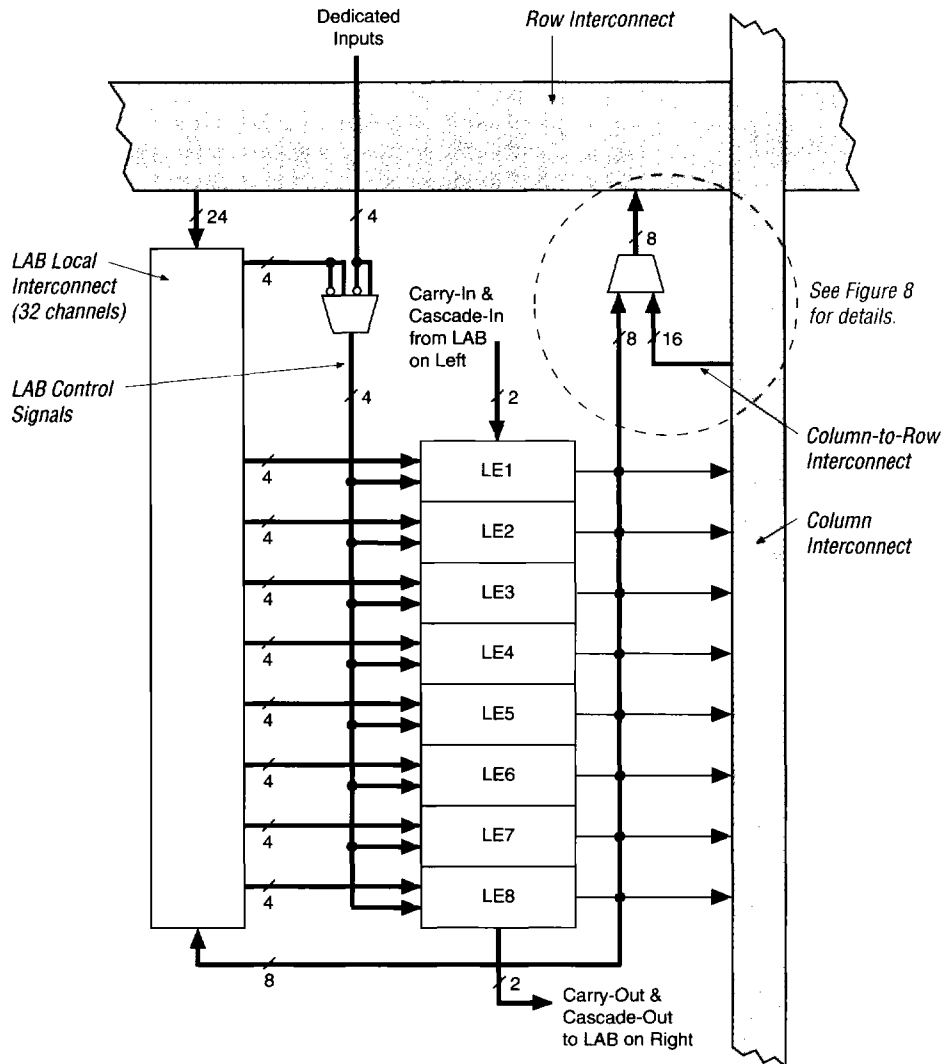


The Clear function is controlled by DATA3, LABCTRL1, and LABCTRL2; the Preset function is controlled by DATA3 and LABCTRL1. The MAX+PLUS II Compiler automatically selects the best control signal implementation during compilation. Since the Clear and Preset functions are active low, the Compiler automatically assigns a logic high to an unused Clear and/or Preset. Preset control can also be provided by using a Clear and inverting the output of the register. Inversion control is available for the inputs to both LEs and IOEs. Therefore, if a register is cleared by only one of the two LABCTRL signals, the DATA3 input is not required and can be used for one of the LE operating modes.

Logic Array Block

A Logic Array Block (LAB) consists of eight LEs, their associated carry and cascade chains, LAB control signals, and the LAB local interconnect. The LAB provides the coarse-grained structure of the FLEX 8000 architecture for efficient routing with high device utilization and high performance. Figure 7 shows a block diagram of the FLEX 8000 LAB.

Figure 7. Logic Array Block (LAB)



Each LAB provides four control signals that can be used in all eight LEs. Two of these signals can be used as Clocks, the other two for Clear/Preset control. The LAB control signals can be driven directly from a dedicated input pin, an I/O pin, or any internal signal via the LAB local interconnect. The dedicated inputs are typically used for global Clock, Clear, or Preset signals because they provide synchronous control with very low skew across the device. If logic is required on a control signal, it can be generated

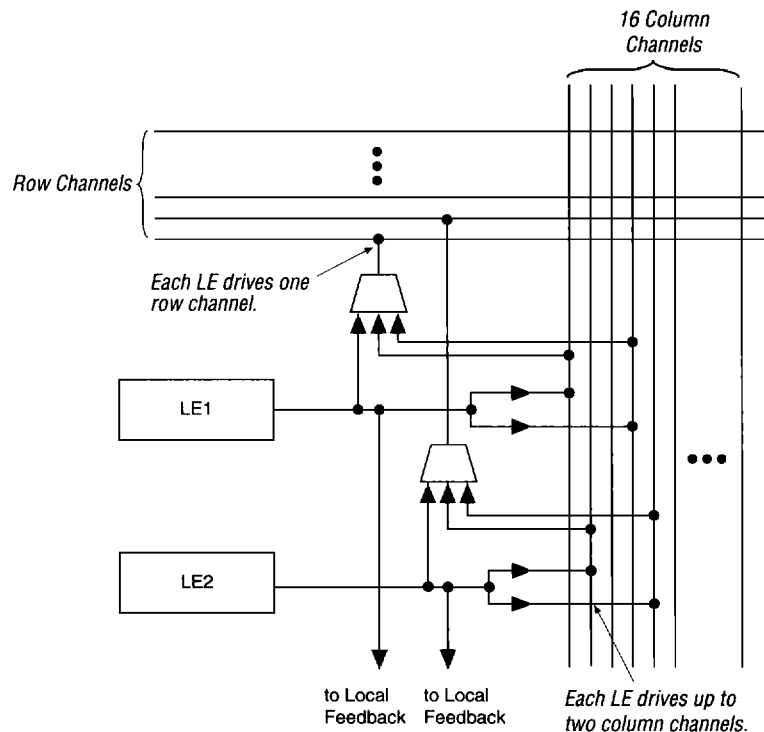
in one or more LEs in any LAB and driven into the local interconnect of the target LAB. Programmable inversion is available for all four LAB control signals.

FastTrack Interconnect

In the FLEX 8000 architecture, connections between LEs and device I/O pins are provided by the FastTrack Interconnect, a series of continuous horizontal and vertical routing channels that traverse the entire FLEX 8000 device. This device-wide routing structure provides predictable performance even in complex designs. In contrast, the segmented routing in FPGAs requires switch matrices to connect a variable number of routing paths, increasing the delays between logic resources and reducing performance.

The LABs within FLEX 8000 devices are arranged into a matrix of columns and rows. Each row of LABs has a dedicated row interconnect that routes signals both into and out of the LABs in the row. The row interconnect can then drive I/O pins or feed other LABs in the device. Figure 8 shows how an LE drives the row and column interconnect.

Figure 8. LAB Connections to Row & Column Interconnect



Each LE in an LAB can drive up to two separate column interconnect channels. Therefore, all 16 available column channels can be driven by the LAB. The column channels run vertically across the entire device, and share access to LABs in the same column but in different rows. The MAX+PLUS II Compiler chooses which LEs must be connected to a column channel. A row interconnect channel can be fed by the output of the LE or by two column channels. These three signals feed a multiplexer that connects to a specific row channel. Each LE is connected to one 3-to-1 multiplexer. In an LAB, the multiplexers provide all 16 column channels with access to 8 row channels.

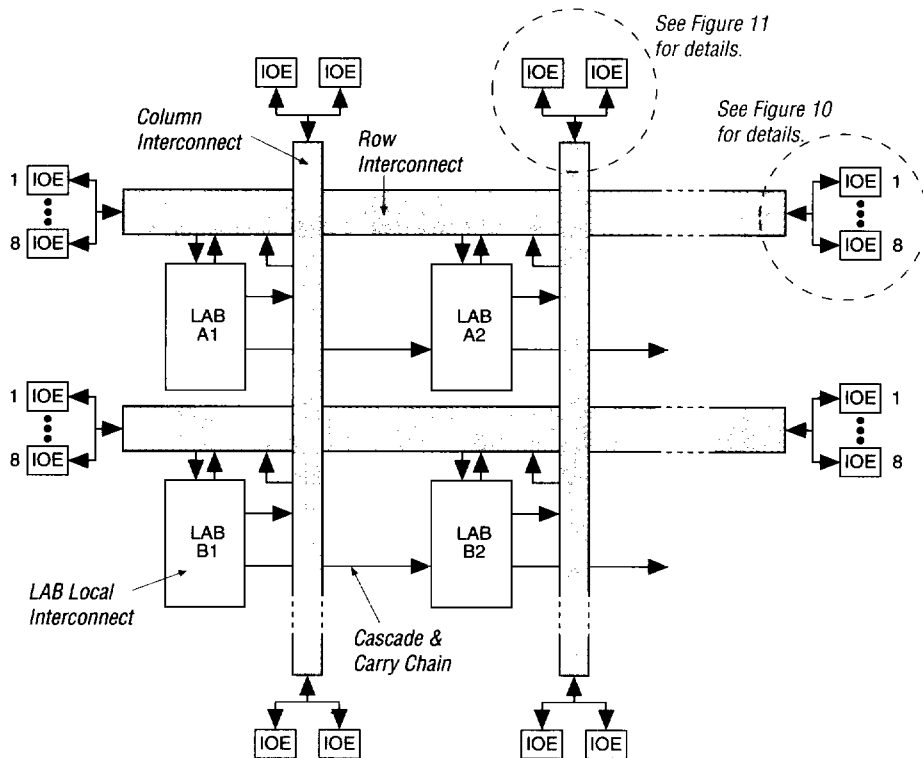
Each column of LABs has a dedicated column interconnect that routes signals out of the LABs into the column. The column interconnect can then drive I/O pins or feed into the row interconnect to route the signals to other LABs in the device. A signal from the column interconnect, which can be either the output of an LE or an input from an I/O pin, must transfer to the row interconnect before it can enter an LAB. Table 3 summarizes the FastTrack Interconnect resources available in each FLEX 8000 device.

Device	Rows	Channels per Row	Columns	Channels per Column
EPF8282 EPF8282V EPF8282A EPF8282AV	2	168	13	16
EPF8452 EPF8452A	2	168	21	16
EPF8636A	3	168	21	16
EPF8820 EPF8820A	4	168	21	16
EPF81188 EPF81188A	6	168	21	16
EPF81500 EPF81500A	6	216	27	16

Figure 9 shows the interconnection of four adjacent LABs, with row, column, and local interconnects, as well as the associated cascade and carry chains.

Figure 9. FLEX 8000 Device Interconnect Resources

Each LAB is named on the basis of its physical row (A, B, C, etc.) and column (1, 2, 3, etc.) position within the device.

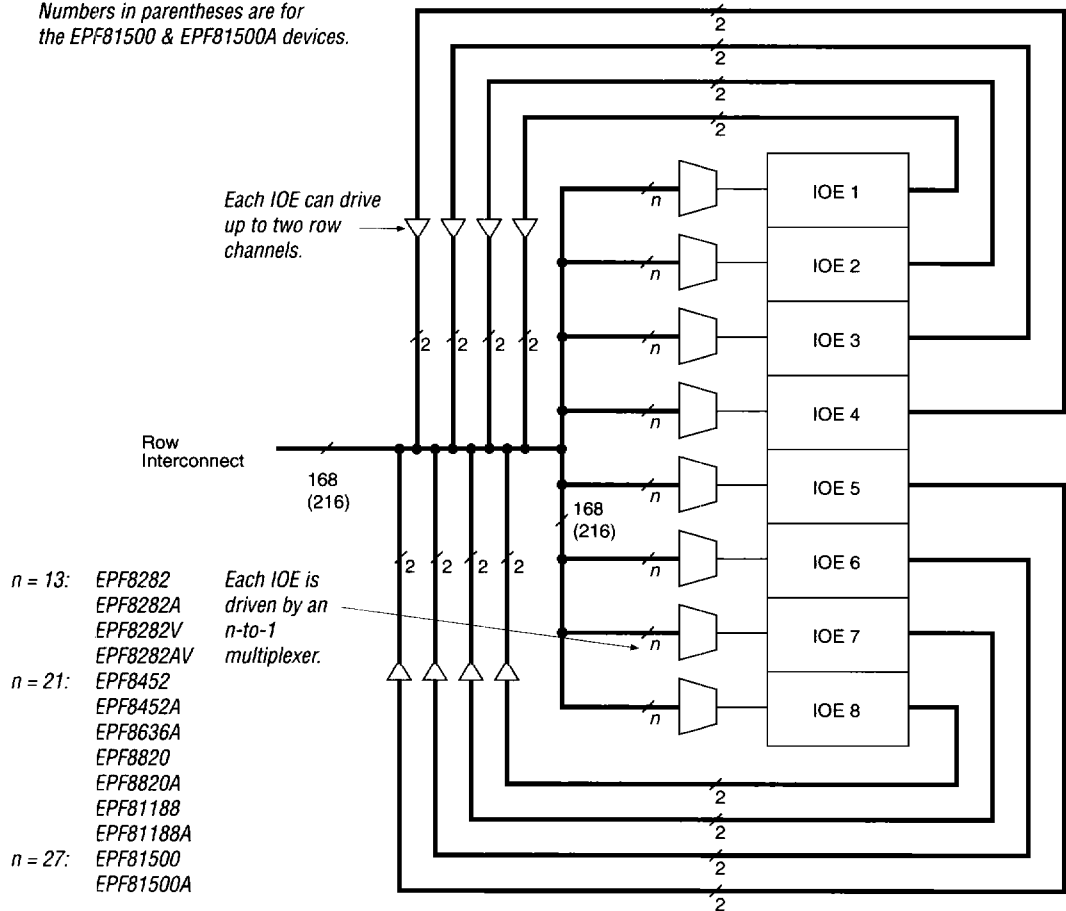


Row-to-IOE Connections

Figure 10 illustrates the connection between row interconnect channels and IOEs. An input signal from an IOE can drive two separate row channels. When an IOE is used as an output, the signal is driven by an n -to-1 multiplexer that selects the row channels. The size of the multiplexer varies with the number of columns in a device. The EPF81500 and EPF81500A use a 27-to-1 multiplexer; the EPF81188, EPF81188A, EPF8820, EPF8820A, EPF8636A, EPF8452, and EPF8452A use a 21-to-1 multiplexer; and the EPF8282, EPF8282A, EPF8282V and EPF8282AV use a 13-to-1 multiplexer. Eight IOEs are connected to each side of the row channels.

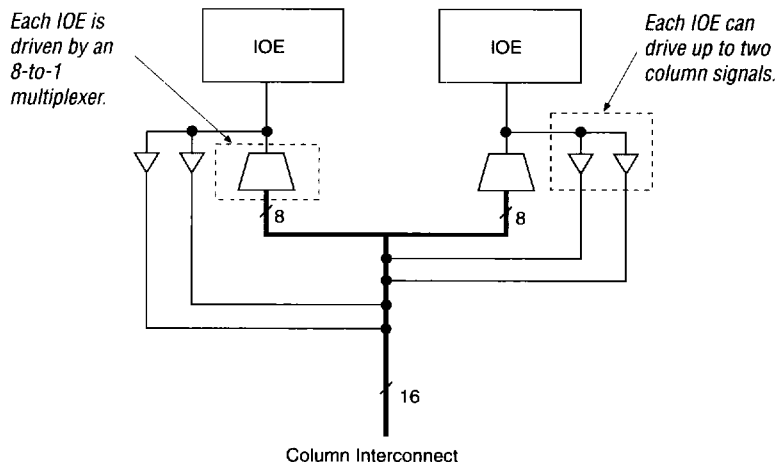
Figure 10. FLEX 8000 Row-to-IOE Connection

Numbers in parentheses are for the EPF81500 & EPF81500A devices.



Column-to-IOE Connections

On the top and bottom of the column channels are two IOEs (see Figure 11). When an IOE is used as an input, it can drive up to 2 separate column channels. The output signal to an IOE can choose from 8 of the 16 column channels through an 8-to-1 multiplexer.

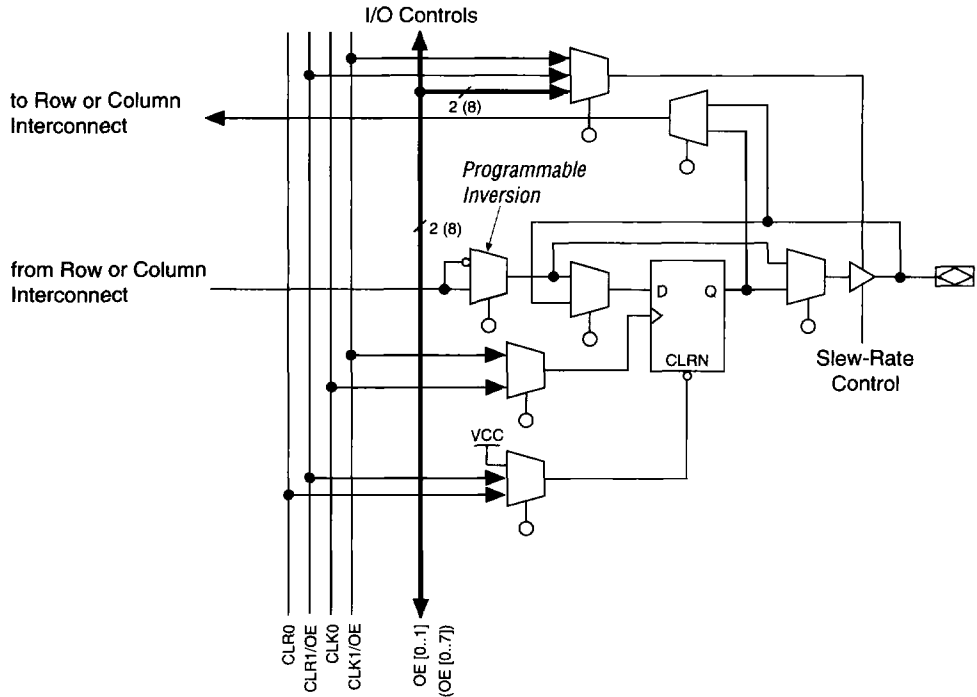
Figure 11. FLEX 8000 Column-to-IOE Connection

In addition to the general-purpose I/O pins, FLEX 8000 devices have four dedicated input pins. These dedicated inputs provide low-skew, device-wide signal distribution, and are typically used for global Clock, Clear, and Preset control signals. The signals from the dedicated inputs are available as control signals for all LABs and I/O elements in the device. The dedicated inputs can also be used as general-purpose data inputs because they can feed the local interconnect of each LAB in the device.

Figure 12 shows the I/O element (IOE) block diagram. Signals enter the FLEX 8000 device either from the I/O pins that provide general-purpose input capability or from the four dedicated inputs. The IOEs are located at the ends of the row and column interconnect channels.

Figure 12. I/O Element (IOE)

Numbers in parentheses are for EPF81500 and EPF81500A devices.



I/O pins can be used as input, output, or bidirectional pins. Each I/O pin has a register that can be used either as an input register for external data that requires fast setup times, or as an output register for data that requires fast Clock-to-output performance. The MAX+PLUS II Compiler uses the programmable inversion option to automatically invert signals from the row and column interconnect when appropriate.

The output buffer in each IOE has an adjustable output slew rate that can be configured for low-noise or high-speed performance. A slower slew rate reduces system noise and adds a maximum delay of 4 ns. The fast slew rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew rate on a pin-by-pin basis during design entry or assign a default slew rate to all pins on a global basis.

The Clock, Clear, and Output Enable controls for the IOEs are provided by a network of I/O control signals. These signals can be supplied by either the dedicated input pins or internal logic. The IOE control-signal paths are designed to minimize the skew across the device. All control-signal sources are buffered onto high-speed drivers that drive the signals around the periphery of the device. This “peripheral bus” can be configured to provide up to four Output Enable signals (ten in the EPF81500 and EPF81500A), and up to two Clock or Clear signals. Figure 12 illustrates how two Output Enable signals are shared with one Clock (CLK1) and one Clear (CLR1) signal.

The signals for the peripheral bus can be generated by any of the 4 dedicated inputs or signals on the row interconnect channels, as shown in Figure 13. The number of row channels used correlates to the number of columns in the FLEX 8000 device. The EPF8282, EPF8282A, EPF8282V, and EPF8282AV, for example, use 13 channels; the EPF8452, EPF8452A, EPF8636A, EPF8820, EPF8820A, EPF81188, and EPF81188A use 21 channels; and the EPF81500 and EPF81500A use 27 channels. The first LE in each LAB is the source of the row channel signal. The 6 peripheral control signals (12 in the EPF81500 and EPF81500A) can be accessed by every I/O element.

Figure 13. FLEX 8000 Peripheral Bus

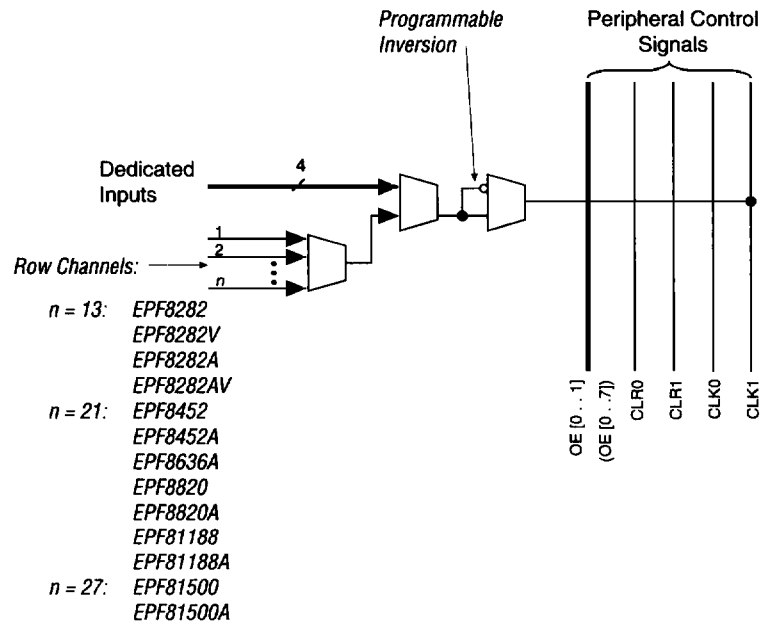


Table 4 lists the row source of the peripheral control signal for each FLEX 8000 device.

Table 4. Row Sources of Peripheral Control Signals

Peripheral Control Signal	EPF8282 EPF8282V EPF8282A EPF8282AV	EPF8452 EPF8452A	EPF8636A	EPF8820 EPF8820A	EPF81188 EPF81188A	EPF81500 EPF81500A
CLK0	Row A	Row A	Row A	Row A	Row E	Row E
CLK1	Row B	Row B	Row C	Row C	Row B	Row B
CLR0	Row A	Row A	Row B	Row B	Row F	Row F
CLR1	Row B	Row B	Row C	Row D	Row C	Row C
OE0	Row A	Row A	Row A	Row A	Row D	Row A
OE1	Row B	Row B	Row B	Row B	Row A	Row A
OE2	–	–	–	–	–	Row B
OE3	–	–	–	–	–	Row C
OE4	–	–	–	–	–	Row D
OE5	–	–	–	–	–	Row D
OE6	–	–	–	–	–	Row E
OE7	–	–	–	–	–	Row F

3.3- or 5.0-V I/O Operation

Some members of the FLEX 8000 family, including EPF81500, EPF81500A, EPF81188, EPF81188A, EPF8820, EPF8820A, and EPF8636A devices (except the 84-pin PLCC EPF8636A) can be set for 3.3-V or 5.0-V operation. These devices have one set of V_{CC} pins for internal operation and input buffers (V_{CCINT}), and another set for I/O output drivers (V_{CCIO}).

The V_{CCINT} pins must always be connected to a 5.0-V power supply. With a 5.0-V V_{CCINT} level, input voltages are at TTL levels and are therefore compatible with 3.3-V and 5.0-V inputs. The V_{CCIO} pins can be connected to either a 3.3-V or 5.0-V power supply, depending on the output requirements. When the V_{CCIO} pins are connected to a 5.0-V power supply, the output levels are compatible with 5.0-V systems. When the V_{CCIO} pins are connected to a 3.3-V power supply, the output high is at 3.3 V and is therefore compatible with 3.3-V systems. Devices operating with a V_{CCIO} levels lower than 4.75 V incur a nominal timing delay adder for the t_{OD} parameter.

JTAG Operation

The EPF8282, EPF8282A, EPF8282V, EPF8282AV, EPF8636A, EPF8820, EPF8820A, EPF81500, and EPF81500A devices support the Joint Test Action Group (JTAG) boundary-scan testing. For detailed information on JTAG operation in these FLEX 8000 devices, refer to *Application Note 39 (JTAG Boundary-Scan Testing in FLEX 8000 Devices)*.

Timing Model

The continuous, high-performance FastTrack Interconnect routing resources ensure predictable performance and accurate simulation analysis. This predictable performance contrasts with that of FPGAs, which use a segmented connection scheme and hence have unpredictable performance. Timing simulation and delay prediction are available with the MAX+PLUS II Simulator and Timing Analyzer, or with industry-standard CAE tools. The Simulator offers both pre-synthesis functional simulation to evaluate logic design accuracy and post-synthesis timing simulation with 0.1-ns resolution. The Timing Analyzer provides point-to-point timing delay information, setup and hold time prediction, and system-level performance analysis.

The FLEX 8000 timing model in Figure 14 shows the delays that correspond to various paths and functions in the circuit. This model contains three distinct parts: the LE; the IOE; and the interconnect, including the row and column FastTrack Interconnect, LAB local interconnect, and carry and cascade interconnect paths. Each parameter shown in Figure 14 is expressed as a worst-case value in the "Internal Timing Characteristics" tables in this data sheet. Hand-calculations that use the FLEX 8000 timing model and these timing parameters can be used to estimate FLEX 8000 device performance. Timing simulation or timing analysis after compilation is required to determine final worst-case performance.

Figure 14. FLEX 8000
Timing Model

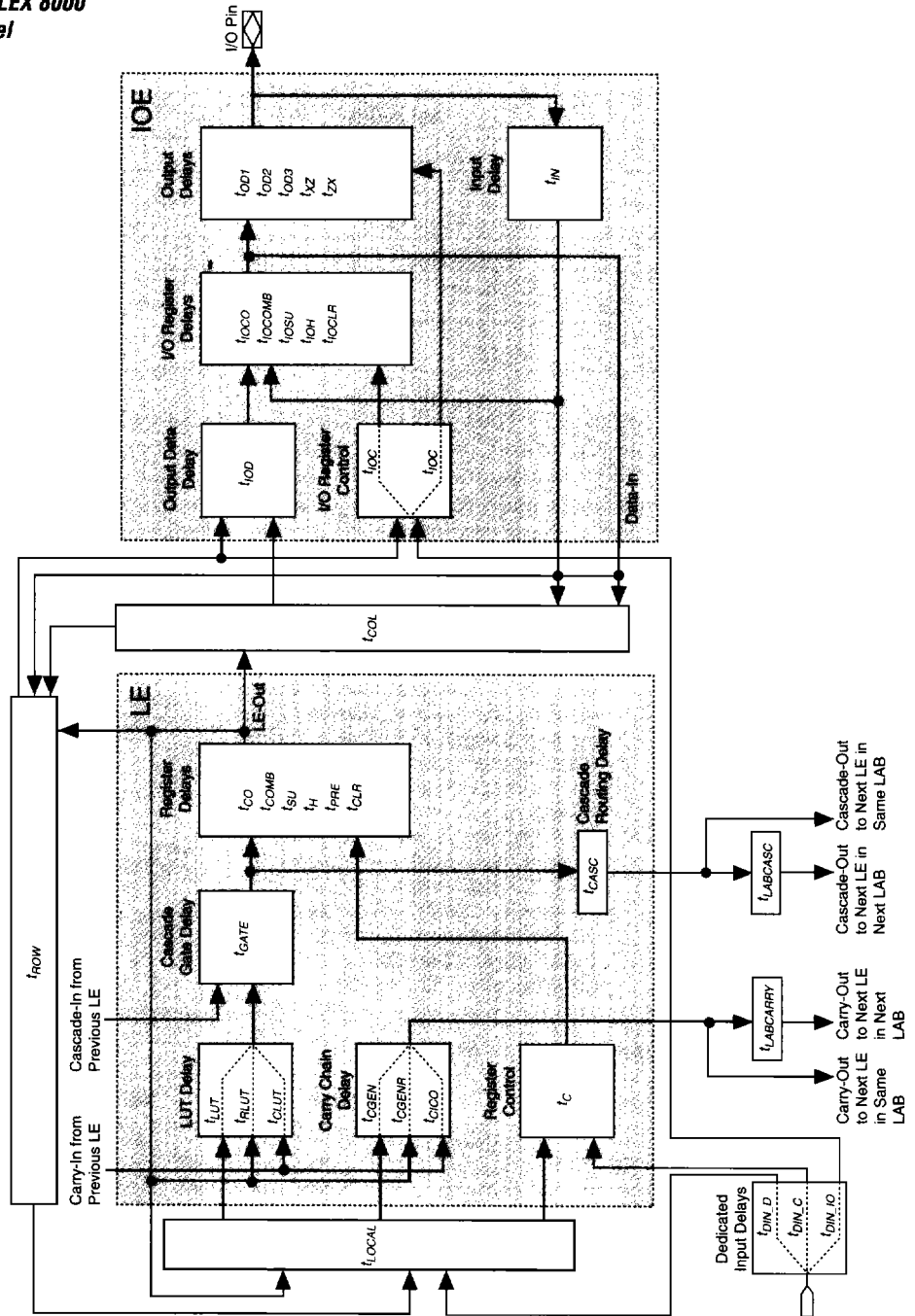


Table 5 outlines the interconnect paths shown in Figure 14.

Table 5. FLEX 8000 Timing Model Interconnect Paths

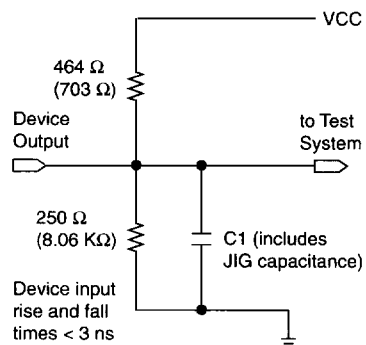
Source	Destination	Total Delay
LE-out	LE in same LAB	t_{LOCAL}
LE-out	LE in same row, different LAB	$t_{ROW} + t_{LOCAL}$
LE-out	LE in different row	$t_{COL} + t_{ROW} + t_{LOCAL}$
LE-out	IOE on column	t_{COL}
LE-out	IOE on row	t_{ROW}
IOE on row	LE in same row	$t_{ROW} + t_{LOCAL}$
IOE on column	Any LE	$t_{COL} + t_{ROW} + t_{LOCAL}$

Generic Testing

Each FLEX 8000 device is functionally tested and guaranteed. Complete testing of each configurable SRAM bit and all logic functionality ensures 100% configuration yield. AC test measurements for FLEX 8000 devices are made under conditions equivalent to those shown in Figure 15. Multiple test patterns can be used to configure devices during all stages of the production flow.

Figure 15. FLEX 8000 AC Test Conditions

Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fast ground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result. Numbers in parentheses are for 3.3-V devices.



FLEX 8000 5.0-V Device Absolute Maximum Ratings

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to GND	-2.0	7.0	V
V_I	DC input voltage	Note (1)	-2.0	7.0	V
I_{OUT}	DC output current, per pin		-25	25	mA
T_{STG}	Storage temperature	No bias	-65	150	°C
T_{AMB}	Ambient temperature	Under bias	-65	135	°C
T_J	Junction temperature	Under bias		150	°C

FLEX 8000 5.0-V Device Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CCINT}	Supply voltage for internal logic and input buffers	With respect to GND, Note (2)	4.75 (4.50)	5.25 (5.50)	V
V _{CCIO}	Supply voltage for output buffers	5.0-V operation, Note (2)	4.75 (4.50)	5.25 (5.50)	V
		3.3-V operation	3.00	3.60	V
V _I	Input voltage		0	V _{CC}	V
V _O	Output voltage		0	V _{CC}	V
T _A	Operating temperature	For commercial use	0	70	°C
T _A	Operating temperature	For industrial use	-40	85	°C
T _C	Case temperature	For military use	-55	125	°C
t _R	Input rise time			40	ns
t _F	Input fall time			40	ns

FLEX 8000 5.0-V Device DC Operating Conditions Notes (3), (4)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{IH}	High-level input voltage		2.0		V _{CC} + 0.3	V
V _{IL}	Low-level input voltage		-0.3		0.8	V
V _{OH}	5.0-V high-level TTL output voltage	I _{OH} = -4 mA DC, V _{CCIO} = 4.75 V	2.4			V
	3.3-V high-level TTL output voltage	I _{OH} = -4 mA DC, V _{CCIO} = 3.00 V	2.4			V
V _{OL}	5.0-V low-level TTL output voltage	I _{OL} = 12 mA DC, V _{CCIO} = 4.75 V			0.45	V
	3.3-V low-level TTL output voltage	I _{OL} = 12 mA DC, V _{CCIO} = 3.00 V			0.45	V
I _I	Input leakage current	V _I = V _{CC} or GND	-10		10	μA
I _{OZ}	Tri-state output off-state current	V _O = V _{CC} or GND	-40		40	μA
I _{CC0}	V _{CC} supply current (standby)	V _I = GND, No load		500		μA

FLEX 8000 5.0-V Device Capacitance Note (5)

Symbol	Parameter	Conditions	Min	Max	Unit
C _{IN}	Input capacitance	V _{IN} = 0 V, f = 1.0 MHz		10	pF
C _{OUT}	Output capacitance	V _{OUT} = 0 V, f = 1.0 MHz		10	pF

Notes to tables:

- Minimum DC input is -0.3 V. During transitions, the inputs may undershoot to -2.0 V or overshoot to 7.0 V for periods shorter than 20 ns under no-load conditions.
- Numbers in parentheses are for military- and industrial-temperature-range versions.
- Typical values are for T_A = 25° C and V_{CC} = 5.0 V.
- Operating conditions:
V_{CCINT} = 5 V ± 5%, T_A = 0° C to 70° C for commercial use.
V_{CCINT} = 5 V ± 10%, T_A = -40° C to 85° C for industrial use.
V_{CCINT} = 5 V ± 10%, T_A = -55° C to 125° C for military use.
- Capacitance is sample-tested only.

Figure 16 shows the typical output drive characteristics of 5.0-V FLEX 8000 devices with 5.0-V V_{CCIO} . The output driver is compatible with the PCI local bus specification.

Figure 16. Output Drive Characteristics for 5.0-V Devices, 5.0-V V_{CCIO}

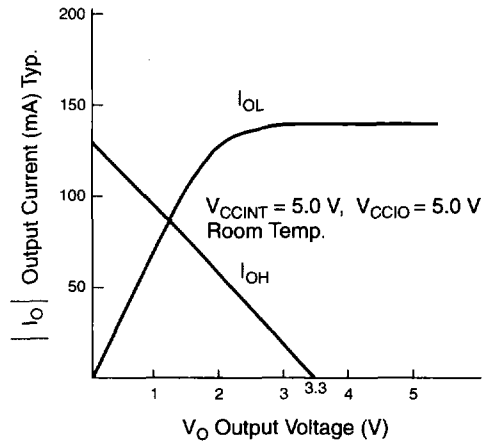
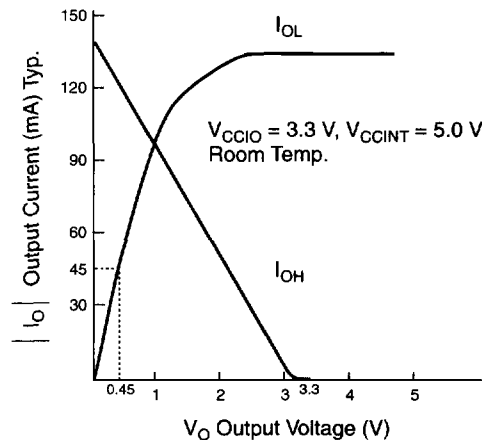


Figure 17 shows the typical output drive characteristics of 5.0-V FLEX 8000 devices with 3.3-V V_{CCIO} . The output driver is compatible with the PCI local bus specification.

Figure 17. Output Drive Characteristics for 5.0-V Devices, 3.3-V V_{CCIO}



FLEX 8000 Internal Timing Characteristics Note (1)

FLEX 8000 I/O Element Timing Parameters (27-Column Devices)			EPF81500-2		EPF81500-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IOD}	IOE register data delay			1.0		2.0	ns
t_{IOC}	IOE register control signal delay			1.0		2.0	ns
t_{IOE}	Output enable delay			1.0		2.0	ns
t_{IOCO}	IOE register clock-to-output delay			1.0		1.0	ns
t_{IOCOMB}	IOE combinatorial delay			0.0		0.0	ns
t_{IOSU}	IOE register setup time before clock		2.0		2.0		ns
t_{IOH}	IOE register hold time after clock		0.0		0.0		ns
t_{IOCLR}	IOE register clear delay			1.2		1.2	ns
t_{IN}	Input pad and buffer delay			1.8		2.8	ns
t_{OD1}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 5.0\text{ V}$	Note (2)		2.0		2.0	ns
t_{OD2}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 3.3\text{ V}$	Note (3)		3.0		3.0	ns
t_{OD3}	Output buffer and pad delay Slow slew rate = on			6.0		6.0	ns
t_{XZ}	Output buffer disable delay			2.0		2.0	ns
t_{ZX}	Output buffer enable delay			2.0		2.0	ns

FLEX 8000 Logic Element Timing Parameters (27-Column Devices)			EPF81500-2		EPF81500-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{LUT}	LUT delay for data-in			4.1		5.1	ns
t_{CLUT}	LUT delay for carry-in			0.2		1.0	ns
t_{RLUT}	LUT delay for LE register feedback			1.9		3.4	ns
t_{GATE}	Cascade gate delay			0.0		0.0	ns
t_{CASC}	Cascade chain routing delay			1.1		2.0	ns
t_{CICO}	Carry-in to carry-out delay			0.7		1.1	ns
t_{CGEN}	Data-in to carry-out delay			0.7		1.4	ns
t_{CGENR}	LE register feedback to carry-out delay			1.7		2.4	ns
t_C	LE register control signal delay			2.8		3.1	ns
t_{CH}	Clock high time			3.5		4.3	ns
t_{CL}	Clock low time			3.5		4.3	ns
t_{CO}	LE register clock-to-output delay			0.4		0.9	ns
t_{COMB}	Combinatorial delay			0.4		0.9	ns
t_{SU}	LE register setup time before clock		1.5		1.7		ns
t_H	LE register hold time after clock		2.3		4.0		ns
t_{PRE}	LE register preset delay			0.7		1.2	ns
t_{CLR}	LE register clear delay			0.7		1.2	ns

FLEX 8000 Interconnect Timing Parameters (27-Column Devices)			EPF81500-2		EPF81500-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
$t_{LABCASC}$	Cascade delay between LEs in different LABs			0.5		0.9	ns
$t_{LABCARRY}$	Carry delay between LEs in different LABs			0.5		0.6	ns
t_{LOCAL}	LAB local interconnect delay			1.0		1.0	ns
t_{ROW}	Row interconnect routing delay	Note (4)		6.2		6.2	ns
t_{COL}	Column interconnect routing delay			3.0		3.0	ns
t_{DIN_C}	Dedicated input to LE control delay			6.0		7.0	ns
t_{DIN_D}	Dedicated input to LE data delay	Note (4)		8.0		9.0	ns
t_{DIN_IO}	Dedicated input to IOE control delay			8.0		9.0	ns

FLEX 8000 External Reference Timing Characteristics (27-Column Devices) Note (5)

			EPF81500-2		EPF81500-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	Test circuit CKT1 Note (6)		34.0		40.2	ns

Notes to tables:

- Internal timing parameters cannot be measured explicitly. The values in these tables are worst-case delays based on testable and guaranteed external parameters. These internal parameters should be used for estimating device performance. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- $V_{CCIO} = 5.0\text{ V} \pm 5\%$ for commercial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for military use.
- $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for commercial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for military use.
- The t_{ROW} and t_{DIN_D} delays are worst-case values for typical applications. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- External reference timing characteristics are factory-tested, guaranteed worst-case values. A representative subset of signal paths is tested to approximate typical device applications.
- Contact Altera Applications at (800) 800-EPLD for more information on test conditions.

FLEX 8000 Internal Timing Characteristics Note (1)

FLEX 8000 I/O Element Timing Parameters (21-Column Devices)			EPF81188-2 EPF8820-2 EPF8452-2		EPF81188-3 EPF8820-3 EPF8452-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IOD}	IOE register data delay			1.0		2.0	ns
t_{IOC}	IOE register control signal delay			1.0		2.0	ns
t_{IOE}	Output enable delay			1.0		2.0	ns
t_{IOCO}	IOE register clock-to-output delay			1.0		1.0	ns
t_{IOCOMB}	IOE combinatorial delay			0.0		0.0	ns
t_{IOSU}	IOE register setup time before clock		2.0		2.0		ns
t_{IOH}	IOE register hold time after clock		0.0		0.0		ns
t_{IOCLR}	IOE register clear delay			1.2		1.2	ns
t_{IN}	Input pad and buffer delay			1.8		2.8	ns
t_{OD1}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 5.0\text{ V}$	Note (2)		2.0		2.0	ns
t_{OD2}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 3.3\text{ V}$	Note (3)		3.0		3.0	ns
t_{OD3}	Output buffer and pad delay Slow slew rate = on			6.0		6.0	ns
t_{XZ}	Output buffer disable delay			2.0		2.0	ns
t_{ZX}	Output buffer enable delay			2.0		2.0	ns

FLEX 8000 Logic Element Timing Parameters (21-Column Devices)			EPF81188-2 EPF8820-2 EPF8452-2		EPF81188-3 EPF8820-3 EPF8452-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{LUT}	LUT delay for data-in			4.1		5.1	ns
t_{CLUT}	LUT delay for carry-in			0.2		1.0	ns
t_{RLUT}	LUT delay for LE register feedback			1.9		3.4	ns
t_{GATE}	Cascade gate delay			0.0		0.0	ns
t_{CASC}	Cascade chain routing delay			1.1		2.0	ns
t_{CICO}	Carry-in to carry-out delay			0.7		1.1	ns
t_{CGEN}	Data-in to carry-out delay			0.7		1.4	ns
t_{CGENR}	LE register feedback to carry-out delay			1.7		2.4	ns
t_C	LE register control signal delay			2.8		3.1	ns
t_{CH}	Clock high time			3.5		4.3	ns
t_{CL}	Clock low time			3.5		4.3	ns
t_{CO}	LE register clock-to-output delay			0.4		0.9	ns
t_{COMB}	Combinatorial delay			0.4		0.9	ns
t_{SU}	LE register setup time before clock		1.5		1.7		ns
t_H	LE register hold time after clock		2.3		4.0		ns
t_{PRE}	LE register preset delay			0.7		1.2	ns
t_{CLR}	LE register clear delay			0.7		1.2	ns

FLEX 8000 Interconnect Timing Parameters (21-Column Devices)			EPF81188-2 EPF8820-2 EPF8452-2		EPF81188-3 EPF8820-3 EPF8452-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
$t_{LABCASC}$	Cascade delay between LEs in different LABs			0.5		0.9	ns
$t_{LABCARRY}$	Carry delay between LEs in different LABs			0.5		0.6	ns
t_{LOCAL}	LAB local interconnect delay			1.0		1.0	ns
t_{ROW}	Row interconnect routing delay	Note (4)		5.0		5.0	ns
t_{COL}	Column interconnect routing delay			3.0		3.0	ns
t_{DIN_C}	Dedicated input to LE control delay			6.0		7.0	ns
t_{DIN_D}	Dedicated input to LE data delay	Note (4)		8.0		9.0	ns
t_{DIN_IO}	Dedicated input to IOE control delay			8.0		9.0	ns

FLEX 8000 External Reference Timing Characteristics Note (5)

			EPF81188-2 EPF8820-2 EPF8452-2		EPF81188-3 EPF8820-3 EPF8452-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	Test circuit CKT1 Note (6)		32.0		38.2	ns

Notes to tables:

- Internal timing parameters cannot be measured explicitly. The values in these tables are worst-case delays based on testable and guaranteed external parameters. These internal parameters should be used for estimating device performance. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- $V_{CCIO} = 5.0\text{ V} \pm 5\%$ for commercial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for military use.
- $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for commercial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for military use. Not valid for the EPF8282, EPF8282A, EPF8452, or EPF8452A devices.
- The t_{ROW} and t_{DIN_D} delays are worst-case values for typical applications. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- External reference timing characteristics are factory-tested, guaranteed worst-case values. A representative subset of signal paths is tested to approximate typical device applications.
- Contact Altera Applications at (800) 800-EPLD for more information on test conditions.

FLEX 8000 Internal Timing Characteristics Note (1)

FLEX 8000 I/O Element Timing Parameters (13-Column Devices)			EPF8282-2		EPF8282-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IOD}	IOE register data delay			1.0		2.0	ns
t_{IOC}	IOE register control signal delay			1.0		2.0	ns
t_{IOE}	Output enable delay			1.0		2.0	ns
t_{IOCO}	IOE register clock-to-output delay			1.0		1.0	ns
t_{IOCOMB}	IOE combinatorial delay			0.0		0.0	ns
t_{IOSU}	IOE register setup time before clock		2.0		2.0		ns
t_{IOH}	IOE register hold time after clock		0.0		0.0		ns
t_{IOCLR}	IOE register clear delay			1.3		1.3	ns
t_{IN}	Input pad and buffer delay			1.8		2.8	ns
t_{OD1}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 5.0$ V	Note (2)		2.5		3.0	ns
t_{OD2}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 3.3$ V	Note (3)		–		–	ns
t_{OD3}	Output buffer and pad delay Slow slew rate = on			6.5		7.0	ns
t_{XZ}	Output buffer disable delay			2.5		3.0	ns
t_{ZX}	Output buffer enable delay			2.5		3.0	ns

FLEX 8000 Logic Element Timing Parameters (13-Column Devices)			EPF8282-2		EPF8282-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{LUT}	LUT delay for data-in			4.1		5.1	ns
t_{CLUT}	LUT delay for carry-in			0.2		1.0	ns
t_{RLUT}	LUT delay for LE register feedback			1.9		3.4	ns
t_{GATE}	Cascade gate delay			0.0		0.0	ns
t_{CASC}	Cascade chain routing delay			1.1		2.0	ns
t_{CICO}	Carry-in to carry-out delay			0.7		1.1	ns
t_{CGEN}	Data-in to carry-out delay			0.7		1.4	ns
t_{CGENR}	LE register feedback to carry-out delay			1.7		2.4	ns
t_C	LE register control signal delay			2.8		3.1	ns
t_{CH}	Clock high time			3.5		4.3	ns
t_{CL}	Clock low time			3.5		4.3	ns
t_{CO}	LE register clock-to-output delay			0.4		0.9	ns
t_{COMB}	Combinatorial delay			0.4		0.9	ns
t_{SU}	LE register setup time before clock		1.5		1.7		ns
t_H	LE register hold time after clock		2.3		4.0		ns
t_{PRE}	LE register preset delay			0.7		1.2	ns
t_{CLR}	LE register clear delay			0.7		1.2	ns

FLEX 8000 Interconnect Timing Parameters (13-Column Devices)			EPF8282-2		EPF8282-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
$t_{LABCASC}$	Cascade delay between LEs in different LABs			0.5		0.9	ns
$t_{LABCARRY}$	Carry delay between LEs in different LABs			0.5		0.6	ns
t_{LOCAL}	LAB local interconnect delay			1.0		1.0	ns
t_{ROW}	Row interconnect routing delay	Note (4)		4.2		4.2	ns
t_{COL}	Column interconnect routing delay			2.5		2.5	ns
t_{DIN_C}	Dedicated input to LE control delay			6.0		7.0	ns
t_{DIN_D}	Dedicated input to LE data delay	Note (4)		7.2		8.2	ns
t_{DIN_IO}	Dedicated input to IOE control delay			7.0		8.0	ns

FLEX 8000 External Reference Timing Characteristics (13-Column Devices) Note (5)

			EPF8282-2		EPF8282-3		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	Test circuit CKT1 Note (6)		29.3		35.5	ns

Notes to tables:

- (1) Internal timing parameters cannot be measured explicitly. The values in these tables are worst-case delays based on testable and guaranteed external parameters. These internal parameters should be used for estimating device performance. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- (2) $V_{CCIO} = 5.0\text{ V} \pm 5\%$ for commercial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for military use.
- (3) $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for commercial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for military use. Not valid for the EPF8282, EPF8282A, EPF8452, or EPF8452A devices.
- (4) The t_{ROW} and t_{DIN_D} delays are worst-case values for typical applications. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- (5) External reference timing characteristics are factory-tested, guaranteed worst-case values. A representative subset of signal paths is tested to approximate typical device applications.
- (6) Contact Altera Applications at (800) 800-EPLD for more information on test conditions.

FLEX 8000A Internal Timing Characteristics *Note (1)*

FLEX 8000A I/O Element Timing Parameters (21-Column Devices)			EPF81188A-3 EPF8636A-3 EPF8452A-3		EPF81188A-4 EPF8636A-4 EPF8452A-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IOD}	IOE register data delay			0.8		0.9	ns
t_{IOC}	IOE register control signal delay			0.8		0.9	ns
t_{IOE}	Output enable delay			0.8		0.9	ns
t_{IOCO}	IOE register clock-to-output delay			0.2		0.2	ns
t_{IOCOMB}	IOE combinatorial delay			0.0		0.0	ns
t_{IOSU}	IOE register setup time before clock		1.6		1.8		ns
t_{IOH}	IOE register hold time after clock		0.0		0.0		ns
t_{IOCLR}	IOE register clear delay			1.2		1.2	ns
t_{IN}	Input pad and buffer delay			1.6		1.7	ns
t_{OD1}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 5.0\text{ V}$	<i>Note (2)</i>		1.0		1.5	ns
t_{OD2}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 3.3\text{ V}$	<i>Note (3)</i>		2.0		2.5	ns
t_{OD3}	Output buffer and pad delay Slow slew rate = on			4.0		4.5	ns
t_{XZ}	Output buffer disable delay			1.0		1.8	ns
t_{ZX}	Output buffer enable delay			1.0		1.8	ns

FLEX 8000A Logic Element Timing Parameters (21-Column Devices)			EPF81188A-3 EPF8636A-3 EPF8452A-3		EPF81188A-4 EPF8636A-4 EPF8452A-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{LUT}	LUT delay for data-in			2.3		3.0	ns
t_{CLUT}	LUT delay for carry-in			0.2		0.1	ns
t_{RLUT}	LUT delay for LE register feedback			1.6		1.6	ns
t_{GATE}	Cascade gate delay			0.0		0.0	ns
t_{CASC}	Cascade chain routing delay			0.7		0.9	ns
t_{CICO}	Carry-in to carry-out delay			0.5		0.6	ns
t_{CGEN}	Data-in to carry-out delay			0.9		0.8	ns
t_{CGENR}	LE register feedback to carry-out delay			1.4		1.5	ns
t_C	LE register control signal delay			1.8		2.4	ns
t_{CH}	Clock high time			1.7		2.7	ns
t_{CL}	Clock low time			1.7		2.7	ns
t_{CO}	LE register clock-to-output delay			0.5		0.6	ns
t_{COMB}	Combinatorial delay			0.5		0.6	ns
t_{SU}	LE register setup time before clock		1.0		1.1		ns
t_H	LE register hold time after clock		1.1		1.4		ns
t_{PRE}	LE register preset delay			0.7		0.8	ns
t_{CLR}	LE register clear delay			0.7		0.8	ns

FLEX 8000A Interconnect Timing Parameters (21-Column Devices)			EPF81188A-3 EPF8636A-3 EPF8452A-3		EPF81188A-4 EPF8636A-4 EPF8452A-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
$t_{LABCASC}$	Cascade delay between LEs in different LABs			0.4		0.4	ns
$t_{LABCARRY}$	Carry delay between LEs in different LABs			0.4		0.4	ns
t_{LOCAL}	LAB local interconnect delay			0.5		0.7	ns
t_{ROW}	Row interconnect routing delay	Note (4)		5.0		5.0	ns
t_{COL}	Column interconnect routing delay			3.0		3.0	ns
t_{DIN_C}	Dedicated input to LE control delay			5.0		5.5	ns
t_{DIN_D}	Dedicated input to LE data delay	Note (4)		7.0		7.5	ns
t_{DIN_IO}	Dedicated input to IOE control delay			7.0		7.5	ns

FLEX 8000A External Reference Timing Characteristics (21-Column Devices) Note (5)

			EPF81188A-3 EPF8636A-3 EPF8452A-3		EPF81188A-4 EPF8636A-4 EPF8452A-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	Test circuit CKT1 Note (6)		20.0		25.0	ns

Notes to tables:

- Internal timing parameters cannot be measured explicitly. The values in these tables are worst-case delays based on testable and guaranteed external parameters. These internal parameters should be used for estimating device performance. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- $V_{CCIO} = 5.0\text{ V} \pm 5\%$ for commercial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for military use.
- $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for commercial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for military use. Not valid for the EPF8282, EPF8282A, EPF8452, or EPF8452A devices.
- The t_{ROW} and t_{DIN_D} delays are worst-case values for typical applications. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- External reference timing characteristics are factory-tested, guaranteed worst-case values. A representative subset of signal paths is tested to approximate typical device applications.
- Contact Altera Applications at (800) 800-EPLD for more information on test conditions.

FLEX 8000A Internal Timing Characteristics Note (1)

FLEX 8000A I/O Element Timing Parameters (21-Column Devices)			EPF81188A-5 EPF8636A-5 EPF8452A-5		EPF81188A-6 EPF8452A-6		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IOD}	IOE register data delay			1.0		2.0	ns
t_{IOC}	IOE register control signal delay			1.0		2.0	ns
t_{IOE}	Output enable delay			1.0		2.0	ns
t_{IOCO}	IOE register clock-to-output delay			1.0		1.0	ns
t_{IOCOMB}	IOE combinatorial delay			0.0		0.0	ns
t_{IOSU}	IOE register setup time before clock		2.0		2.0		ns
t_{IOH}	IOE register hold time after clock		0.0		0.0		ns
t_{IOCLR}	IOE register clear delay			1.2		1.2	ns
t_{IN}	Input pad and buffer delay			1.8		2.8	ns
t_{OD1}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 5.0$ V	Note (2)		2.0		2.0	ns
t_{OD2}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 3.3$ V	Note (3)		3.0		3.0	ns
t_{OD3}	Output buffer and pad delay Slow slew rate = on			5.0		6.0	ns
t_{XZ}	Output buffer disable delay			2.0		2.0	ns
t_{ZX}	Output buffer enable delay			2.0		2.0	ns

FLEX 8000A Logic Element Timing Parameters (21-Column Devices)			EPF81188A-5 EPF8636A-5 EPF8452A-5		EPF81188A-6 EPF8452A-6		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{LUT}	LUT delay for data-in			3.7		5.1	ns
t_{CLUT}	LUT delay for carry-in			0.1		1.0	ns
t_{RLUT}	LUT delay for LE register feedback			1.9		3.4	ns
t_{GATE}	Cascade gate delay			0.0		0.0	ns
t_{CASC}	Cascade chain routing delay			1.1		2.0	ns
t_{CICO}	Carry-in to carry-out delay			0.7		1.1	ns
t_{CGEN}	Data-in to carry-out delay			0.9		1.4	ns
t_{CGENR}	LE register feedback to carry-out delay			1.8		2.4	ns
t_C	LE register control signal delay			2.9		3.1	ns
t_{CH}	Clock high time			3.4		4.3	ns
t_{CL}	Clock low time			3.4		4.3	ns
t_{CO}	LE register clock-to-output delay			0.7		0.9	ns
t_{COMB}	Combinatorial delay			0.7		0.9	ns
t_{SU}	LE register setup time before clock		1.2		1.7		ns
t_H	LE register hold time after clock		1.8		4.0		ns
t_{PRE}	LE register preset delay			0.9		1.2	ns
t_{CLR}	LE register clear delay			0.9		1.2	ns

FLEX 8000A Interconnect Timing Parameters (21-Column Devices)			EPF81188A-5 EPF8636A-5 EPF8452A-5		EPF81188A-6 EPF8452A-6		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
$t_{LABCASC}$	Cascade delay between LEs in different LABs			0.5		0.9	ns
$t_{LABCARRY}$	Carry delay between LEs in different LABs			0.5		0.6	ns
t_{LOCAL}	LAB local interconnect delay			0.9		1.0	ns
t_{ROW}	Row interconnect routing delay	Note (4)		5.0		5.0	ns
t_{COL}	Column interconnect routing delay			3.0		3.0	ns
t_{DIN_C}	Dedicated input to LE control delay			6.0		7.0	ns
t_{DIN_D}	Dedicated input to LE data delay	Note (4)		8.0		9.0	ns
t_{DIN_IO}	Dedicated input to IOE control delay			7.0		9.0	ns

FLEX 8000A External Reference Timing Characteristics (21-Column Devices) Note (5)

			EPF81188A-5 EPF8636A-5 EPF8452A-5		EPF81188A-6 EPF8452A-6		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	Test circuit CKT1 Note (6)		30.0		38.2	ns

Notes to tables:

- Internal timing parameters cannot be measured explicitly. The values in these tables are worst-case delays based on testable and guaranteed external parameters. These internal parameters should be used for estimating device performance. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- $V_{CCIO} = 5.0\text{ V} \pm 5\%$ for commercial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 5.0\text{ V} \pm 10\%$ for military use.
- $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for commercial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for industrial use.
 $V_{CCIO} = 3.3\text{ V} \pm 10\%$ for military use. Not valid for the EPF8282, EPF8282A, EPF8452, or EPF8452A devices.
- The t_{ROW} and t_{DIN_D} delays are worst-case values for typical applications. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- External reference timing characteristics are factory-tested, guaranteed worst-case values. A representative subset of signal paths is tested to approximate typical device applications.
- Contact Altera Applications at (800) 800-EPLD for more information on test conditions.

Calculating Supply Current for 5.0-V FLEX 8000 Devices

The V_{CC} supply current for 5.0-V FLEX 8000 devices, I_{CC} , can be calculated with the following equation:

$$I_{CC} = I_{CC\text{STANDBY}} + I_{CC\text{OUTPUT}} + I_{CC\text{ACTIVE}}$$

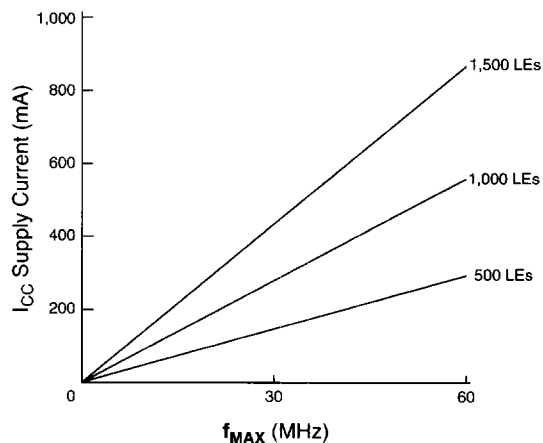
Typical $I_{CC\text{STANDBY}}$ values are shown as I_{CC0} in the “FLEX 8000 5.0-V Device DC Operating Conditions” table earlier in this data sheet. The $I_{CC\text{OUTPUT}}$ value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Operating Requirements for Altera Devices* in the current *Data Book*. The $I_{CC\text{ACTIVE}}$ value depends on the switching frequency and the application logic. This value can be calculated on the basis of the relationship that each LE typically consumes 75 $\mu\text{A}/\text{MHz}$. The following equation shows the general formula for calculating $I_{CC\text{ACTIVE}}$:

$$I_{CC\text{ACTIVE}} = 75 \times \frac{\mu\text{A}}{\text{MHz} \cdot \text{LE}} \times F \times N \times 0.125$$

In this equation, F is the maximum operating frequency in MHz; N is the number of LEs used in the device. The total is multiplied by 0.125, which is based on a 16-bit counter in which 2 out of 16 (12.5%) of the output bits switch on each Clock edge.

Figure 18 shows the relationship between I_{CC} and operating frequency for LE utilization values ranging from 500 to 1,500 LEs.

Figure 18. FLEX 8000 $I_{CC\text{ACTIVE}}$ vs. Operating Frequency



FLEX 8000 3.3-V Device Absolute Maximum Ratings

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to GND	-2.0	7.0	V
V_I	DC input voltage	Note (1)	-2.0	7.0	V
I_{OUT}	DC output current, per pin		-25	25	mA
T_{STG}	Storage temperature	No bias	-65	150	°C
T_{AMB}	Ambient temperature	Under bias	-65	135	°C
T_J	Junction temperature	Under bias		150	°C

FLEX 8000 3.3-V Device Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to GND	3.0	3.6	V
V_I	Input voltage		0	V_{CC}	V
V_O	Output voltage		0	V_{CC}	V
T_A	Operating temperature	For commercial use	0	70	°C
t_R	Input rise time			40	ns
t_F	Input fall time			40	ns

FLEX 8000 3.3-V Device DC Operating Conditions Note (2)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IH}	High-level input voltage		2.0		$V_{CC} + 0.3$	V
V_{IL}	Low-level input voltage		-0.3		0.8	V
V_{OH}	High-level output voltage	$I_{OH} = 0.1$ mA DC	$V_{CC} - 0.2$			V
V_{OL}	Low-level output voltage	$I_{OL} = 4$ mA DC			0.45	V
I_I	Input leakage current	$V_I = V_{CC}$ or GND	-10		10	μA
I_{OZ}	Tri-state output off-state current	$V_O = V_{CC}$ or GND	-40		40	μA
I_{CC0}	V_{CC} supply current (standby)	$V_I =$ GND, No load, Note (3)		300		μA

FLEX 8000 3.3-V Device Capacitance Note (4)

Symbol	Parameter	Conditions	Min	Max	Unit
C_{IN}	Input capacitance	$V_{IN} = 0$ V, $f = 1.0$ MHz		10	pF
C_{OUT}	Output capacitance	$V_{OUT} = 0$ V, $f = 1.0$ MHz		10	pF

FLEX 8000 3.3-Volt Device Internal Timing Characteristics *Note (1)*

EPF8282V I/O Element (IOE) Timing Parameters			EPF8282V-3		EPF8282V-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{IOD}	IOE register data delay			2.2		3.5	ns
t_{IOC}	IOE register control signal delay			2.0		3.4	ns
t_{IOE}	Output enable delay			2.0		3.4	ns
t_{IOCO}	IOE register clock-to-output delay			2.0		3.0	ns
t_{IOCOMB}	IOE combinatorial delay			0.0		0.0	ns
t_{IOSU}	IOE register setup time before clock		2.8		4.7		ns
t_{IOH}	IOE register hold time after clock		0.2		0.1		ns
t_{IOCLR}	IOE register clear delay			2.3		3.5	ns
t_{IN}	Input pad and buffer delay			3.4		5.4	ns
t_{OD1}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 3.3\text{ V}$	<i>Note (2)</i>		3.1		5.6	ns
t_{OD2}	Output buffer and pad delay Slow slew rate = off, $V_{CCIO} = 5.0\text{ V}$	<i>Note (5)</i>		–		–	ns
t_{OD3}	Output buffer and pad delay Slow slew rate = on			7.1		9.6	ns
t_{XZ}	Output buffer disable delay			4.3		6.7	ns
t_{ZX}	Output buffer enable delay			4.3		6.7	ns

EPF8282V Logic Element (LE) Timing Parameters			EPF8282V-3		EPF8282V-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{LUT}	LUT delay for data-in			7.3		14.3	ns
t_{CLUT}	LUT delay for carry-in			1.4		1.3	ns
t_{RLUT}	LUT delay for LE register feedback			5.1		7.3	ns
t_{GATE}	Cascade gate delay			0.0		0.0	ns
t_{CASC}	Cascade chain routing delay			2.8		4.2	ns
t_{CICO}	Carry-in to carry-out delay			1.5		2.2	ns
t_{CGEN}	Data-in to carry-out delay			2.2		4.5	ns
t_{CGENR}	LE register feedback to carry-out delay			3.7		6.0	ns
t_C	LE register control signal delay			4.7		9.5	ns
t_{CH}	Clock high time			6.0		10.5	ns
t_{CL}	Clock low time			6.0		10.5	ns
t_{CO}	LE register clock-to-output delay			0.9		0.9	ns
t_{COMB}	Combinatorial delay			0.9		0.9	ns
t_{SU}	LE register setup time before clock		2.4		4.4		ns
t_H	LE register hold time after clock		4.6		6.8		ns
t_{PRE}	LE register preset delay			1.3		1.6	ns
t_{CLR}	LE register clear delay			1.3		1.6	ns

EPF8282V Interconnect Timing Parameters			EPF8282V-3		EPF8282V-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
$t_{LABCASC}$	Cascade delay between LEs in different LABs			1.3		2.0	ns
$t_{LABCARRY}$	Carry delay between LEs in different LABs			0.8		1.2	ns
t_{LOCAL}	LAB local interconnect delay			1.5		1.5	ns
t_{ROW}	Row interconnect routing delay	Note (3)		6.3		6.3	ns
t_{COL}	Column interconnect routing delay			3.8		3.8	ns
t_{DIN_C}	Dedicated input to LE control delay			8.0		10.3	ns
t_{DIN_D}	Dedicated input to LE data delay			9.8		12.3	ns
t_{DIN_IO}	Dedicated input to IOE control delay			10.0		12.3	ns

FLEX 8000 3.3-V External Reference Timing Characteristics (13-Column Devices) Note (4)

			EPF8282V-3		EPF8282V-4		
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t_{DRR}	Register-to-register delay via 4 LEs, 3 row interconnects, and 4 local interconnects	Test circuit CKT1 Note (6)		50.4		80.4	ns

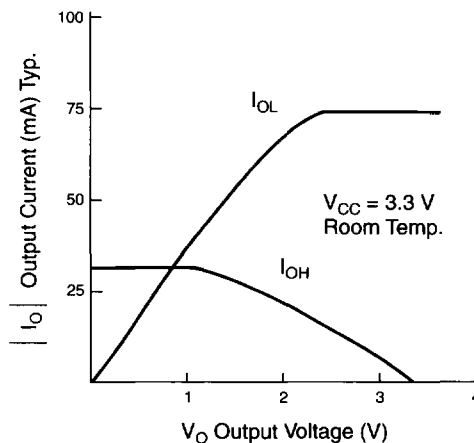
Notes to tables:

- (1) Minimum DC input is -0.3 V. During transitions, the inputs may undershoot to -2.0 V or overshoot to 7.0 V for periods shorter than 20 ns under no-load conditions.
- (2) $V_{CCIO} = 3.3$ V \pm 10% for commercial use.
 $V_{CCIO} = 3.3$ V \pm 10% for industrial use.
 $V_{CCIO} = 3.3$ V \pm 10% for military use.
- (3) The t_{ROW} and t_{DIN_D} delays are worst-case values for typical applications. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.
- (4) Capacitance is sample-tested only.
- (5) Not valid for the EPF8282V device.
- (6) Internal timing parameters cannot be measured explicitly. The values in these tables are worst-case delays based on testable and guaranteed external parameters. These internal parameters should be used for estimating device performance. Post-compilation timing simulation or timing analysis is required to determine actual worst-case performance.

Calculating Supply Current for 3.3-V FLEX 8000 Devices

Figure 19 shows the typical output drive characteristics of EPF8282V I/O pins.

Figure 19. EPF8282V Typical Output Drive Characteristics



The V_{CC} supply current for 3.3-V FLEX 8000 devices, I_{CC} , can be calculated with the following equation:

$$I_{CC} = I_{CC\text{STANDBY}} + I_{CC\text{OUTPUT}} + I_{CC\text{ACTIVE}}$$

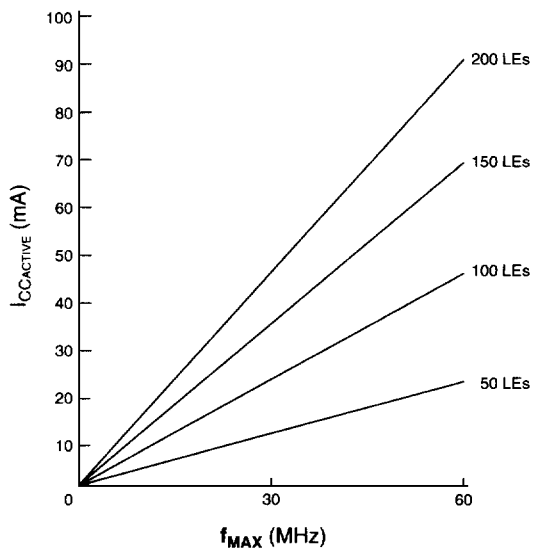
Typical $I_{CC\text{STANDBY}}$ values are shown as I_{CC0} in the "FLEX 8000 3.3-V Device DC Operating Conditions" table earlier in this data sheet. The $I_{CC\text{OUTPUT}}$ value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Operating Requirements for Altera Devices* in the current *Data Book*. The $I_{CC\text{ACTIVE}}$ value depends on the switching frequency and the application logic. This value can be based on a typical current consumption of 60 $\mu\text{A}/\text{MHz}$ per LE. The following equation shows the general formula for calculating $I_{CC\text{ACTIVE}}$:

$$I_{CC\text{ACTIVE}} = 60 \times \frac{\mu\text{A}}{\text{MHz} \cdot \text{LE}} \times F \times N \times 0.125$$

In this equation, F is the maximum operating frequency in MHz and N is the number of LEs used in the device. The equation is multiplied by the typical percentage of LEs that switch on each Clock edge. The value 0.125 is based on a 16-bit counter in which 2 out of 16 (12.5%) of the bits switch on each Clock edge.

Figure 20 shows the relationship between $I_{CCACTIVE}$ and the operating frequency for LE utilization values ranging from 50 to 200 LEs.

Figure 20. EPF8282V $I_{CCACTIVE}$ vs. Operating Frequency



Configuration & Operation

The FLEX 8000 architecture supports several configuration schemes to load a design into the device(s) on the circuit board. This data sheet summarizes the device operating modes and available device configuration schemes. Refer to *Application Note 33 (Configuring FLEX 8000 Devices)* and *Application Note 38 (Configuring Multiple FLEX 8000 Devices)* for detailed descriptions of device configuration options; device configuration pins; and information on configuring FLEX 8000 devices, including sample schematics, timing diagrams, and configuration parameters.

Operating Modes

The FLEX 8000 architecture uses SRAM technology that requires configuration data to be loaded whenever the circuit powers up and begins operation. The process of physically loading the SRAM programming data into the device is called configuration. During initialization, which occurs immediately after configuration, the device resets registers, enables I/O pins, and begins to operate as a logic device. The configuration and initialization processes together are called "command mode"; normal device operation is called "user mode."

The SRAM technology allows FLEX 8000 devices to be reconfigured in-circuit by loading new programming data into the device. Real-time reconfiguration is performed by forcing the device into command mode with a device pin, loading different programming data, reinitializing the device, and resuming user-mode operation. The entire reconfiguration process requires less than 100 ms and can be used to dynamically reconfigure an entire system. In-field upgrades can be performed by distributing new configuration files.

Configuration Schemes

The configuration data for a FLEX 8000 device can be loaded with one of six configuration schemes, chosen on the basis of the target application. Both active and passive schemes are available. In the active configuration schemes, the FLEX 8000 device functions as the controller, directing the loading operation, controlling external EPROM devices, and completing the loading process. The Clock source for all active configuration schemes is an oscillator on the FLEX 8000 device that operates between 2 MHz and 6 MHz. In the passive configuration schemes, an external controller guides the FLEX 8000 device, which operates as a slave. Table 6 shows the source of data for each of the six configuration schemes.

Table 6. Configuration Schemes		
Configuration Scheme	Acronym	Data Source
Active serial	AS	Altera Configuration EPROM
Active parallel up	APU	Parallel EPROM
Active parallel down	APD	Parallel EPROM
Passive serial	PS	Serial data path
Passive parallel synchronous	PPS	Intelligent host
Passive parallel asynchronous	PPA	Intelligent host

MAX+PLUS II Development System

FLEX 8000 devices are supported by Altera's MAX+PLUS II development system. MAX+PLUS II also supports the Altera Classic, MAX 5000, and MAX 7000 device families.

Designs can be entered as logic schematics with the Graphic Editor; as state machines, truth tables, conditional logic, and Boolean equations with the Altera Hardware Description Language (AHDL), VHSIC Hardware Description Language (VHDL), or Verilog HDL; or as waveforms with the Waveform Editor. Logic synthesis and minimization automatically optimize the logic of a design. MAX+PLUS II also provides automatic design partitioning into multiple devices from the same family. Design verification and timing analysis are performed with the built-in Simulator and Timing Analyzer. Errors in a design can be automatically located and highlighted in the original design files.

MAX+PLUS II software runs on 486- and Pentium-based PCs, as well as Sun SPARCstations, HP 9000 Series 700, and DEC Alpha AXP workstations. It gives designers the tools to create complex logic designs quickly and efficiently. MAX+PLUS II provides an EDIF netlist interface for additional design entry and simulation support with popular CAE tools from Cadence, Mentor Graphics, Synopsys, Viewlogic, Intergraph, Logic Modeling, and others. MAX+PLUS II also exports Verilog HDL and VHDL netlist files for use with other industry-standard design verification tools.

Altera's FLEX 8000-compatible programming hardware includes the Altera Logic Programmer card, the Master Programming Unit (MPU), and various device adapters. The MPU supports continuity checking to ensure adequate electrical contact between the adapter and the device. Configuration EPROM device adapters are shipped with the FLEX Download Cable, which allows users to configure FLEX 8000 devices in-circuit with Altera programming hardware and the MAX+PLUS II Programmer. For more information on programming hardware, see *Altera Programming Hardware* in the current Altera *Data Book*. FLEX 8000 devices can also be configured in-circuit via a standard RS-232 serial port from a workstation or PC using the BitBlaster, a hardware box that provides a download cable to a FLEX 8000 device. For more information on the BitBlaster, refer to the *BitBlaster Serial Download Cable Data Sheet*. Further details about the MAX+PLUS II development system are available in the current *MAX+PLUS II Programmable Logic Development System & Software Data Sheet*.

Thermal Characteristics

The following formulas are used to calculate the maximum allowed power (P_{MAX}) for a device:

$$P_{MAX} = \frac{150^{\circ}\text{C} - T_{AMB}}{\theta_{JA}}$$

or

$$P_{MAX} = \frac{150^{\circ}\text{C} - T_C}{\theta_{JC}}$$

The maximum allowable power is dependent on the maximum allowable junction temperature of the silicon (T_J), the ambient temperature of operation (T_{AMB}), and the package's thermal resistance (θ_j) when operating in the system. θ_{JC} is a measure of the lowest possible thermal resistance and is used to calculate maximum power when the case temperature (T_{CASE}) of the device is known. The maximum junction temperature for all FLEX 8000 devices is 150° C. The ambient temperature is dependent on the application. Table 7 lists the thermal resistance values for junction-to-case (θ_{JC}), and junction-to-ambient (θ_{JA}) over different air-flow conditions.

Device	Pin Count	Package	θ_{JC} (C/W)	θ_{JA} (C/W) Still Air	θ_{JA} (C/W) 100 ft./min.	θ_{JA} (C/W) 200 ft./min.	θ_{JA} (C/W) 400 ft./min.
EPF8282	84	PLCC	11	35	23, <i>Note (2)</i>	18, <i>Note (2)</i>	14, <i>Note (2)</i>
EPF8282V	100	TQFP	C.F.	C.F.	C.F.	C.F.	C.F.
EPF8452	84	PLCC	11	35	23, <i>Note (2)</i>	18, <i>Note (2)</i>	14, <i>Note (2)</i>
EPF8452A	160	PQFP	7	40	26, <i>Note (2)</i>	20, <i>Note (2)</i>	16, <i>Note (2)</i>
	160	PGA	6	20	13, <i>Note (2)</i>	10, <i>Note (2)</i>	8, <i>Note (2)</i>
EPF8636A	84	PLCC	11, <i>Note (2)</i>	35, <i>Note (2)</i>	23, <i>Note (2)</i>	18, <i>Note (2)</i>	14, <i>Note (2)</i>
	192	PGA	6	16	11, <i>Note (2)</i>	8, <i>Note (2)</i>	6, <i>Note (2)</i>
	208	RQFP	2	18	12	9	7
EPF8820	192	PGA	6	16	11, <i>Note (2)</i>	8, <i>Note (2)</i>	6, <i>Note (2)</i>
	208	RQFP	2	18	12	9	7
	225	BGA	6	28	19	14	11
EPF81188	232	PGA	2	14	10	7	5
EPF81188A	240	RQFP	2	20	13, <i>Note (2)</i>	10, <i>Note (2)</i>	8, <i>Note (2)</i>
EPF81500	280	PGA	2, <i>Note (2)</i>	14, <i>Note (2)</i>	10, <i>Note (2)</i>	7, <i>Note (2)</i>	5, <i>Note (2)</i>
	304	RQFP	2, <i>Note (2)</i>	20, <i>Note (2)</i>	13, <i>Note (2)</i>	10, <i>Note (2)</i>	8, <i>Note (2)</i>

Notes:

- (1) This table is based on an ambient temperature (T_{AMB}) of 25° C.
- (2) This information is preliminary.

Device Pin-Outs Tables 8 through 10 show the pin names and numbers for each FLEX 8000 device package.

Table 8. FLEX 8000 84-, 100- & 160-Pin Package Pin-Outs (Part 1 of 2)

Pin Name	84-Pin PLCC EPF8452 EPF8452A EPF8636A	84-Pin PLCC EPF8282	100-Pin TQFP EPF8282	160-Pin PGA EPF8452 EPF8452A	160-Pin PQFP EPF8452 EPF8452A
nSP (1)	75	75	75	R1	120
MSEL0 (1)	74	74	74	P2	117
MSEL1 (1)	53	53	51	A1	84
nSTATUS (1)	32	32	24	C13	37
nCONFIG (1)	33	33	25	A15	40
DCLK (1)	10	10	100	P14	1
nWS	30	30	22	F13	30
CONF_DONE (1)	11	11	1	N13	4
nRS	48	48	42	C6	71
RDCLK	49	49	45	B5	73
nCS	29	29	21	D15	29
CS	28	28	19	E15	27
RDYnBUSY	77	77	77	P3	125
CLKUSR	50	50	47	C5	76
ADD17	51	51	49	B4	78
ADD16	55	36	28	E2	91
ADD15	56	56	55	D1	92
ADD14	57	57	57	E1	94
ADD13	58	58	58	F3	95
ADD12	60	60	59	F2	96
ADD11	61	61	60	F1	97
ADD10	62	62	61	G2	98
ADD9	63	63	62	G1	99
ADD8	64	64	64	H1	101
ADD7	65	65	65	H2	102
ADD6	66	66	66	J1	103
ADD5	67	67	67	J2	104
ADD4	69	69	68	K2	105
ADD3	70	70	69	K1	106
ADD2	71	71	71	K3	109
ADD1	72	76	76	M1	110

Table 8. FLEX 8000 84-, 100- & 160-Pin Package Pin-Outs (Part 2 of 2)

Pin Name	84-Pin PLCC EPF8452 EPF8452A EPF8636A	84-Pin PLCC EPF8282	100-Pin TQFP EPF8282	160-Pin PGA EPF8452 EPF8452A	160-Pin PQFP EPF8452 EPF8452A
ADD0	76	78	78	N3	123
DATA7	2	3	90	P8	144
DATA6	4	4	91	P10	150
DATA5	6	6	92	R12	152
DATA4	7	7	95	R13	154
DATA3	8	8	97	P13	157
DATA2	9	9	99	R14	159
DATA1	13	13	4	N15	11
DATA0	14	14	5	K13	12
TDI (2)	45 (3)	55	54	–	–
TDO (2)	27 (3)	27	18	–	–
TCLK (2)	44 (3)	72	72	–	–
TMS (2)	43 (3)	20	11	–	–
nTRST (1)	52 (4)	52	50	–	–
Dedicated Inputs	12, 31, 54, 73	12, 31, 54, 73	3, 23, 53, 73	C3, D14, N2, R15	5, 36, 85, 116
VCC	17, 38, 59, 80	17, 38, 59, 80	6, 20, 37, 56, 70, 87	B2, C4, D3, D8, D12, G3, G12, H4, H13, J3, J12, M4, M7, M9, M13, N12	21, 41, 53, 67, 80, 81, 100, 121, 133, 147, 160
GND	5, 26, 47, 68	5, 26, 47, 68	2, 13, 30, 44, 52, 63, 80, 94	C12, D4, D7, D9, D13, G4, G13, H3, H12, J4, J13, L1, M3, M8, M12, M15, N4	13, 14, 28, 46, 60, 75, 93, 107, 108, 126, 140, 155
No Connect (N.C.)	–	–	–	–	2, 3, 38, 39, 70, 82, 83, 118, 119, 148
Total User I/O Pins	64	64	74	116	116

Notes to Table 8:

- (1) Dedicated pin (not available as a user I/O pin).
- (2) If the device is not configured to use the JTAG BST circuitry, this pin is available as a user I/O pin.
- (3) Dedicated JTAG pins are available for EPF8636A devices only. No dedicated JTAG pins are available for EPF8452 and EPF8452A devices.
- (4) Pin 52 is a V_{CC} pin on EPF8452 and EPF8452A devices only.

Table 9. FLEX 8000 192-, 208- & 225-Pin Package Pin-Outs (Part 1 of 3)

Pin Name	192-Pin PGA EPF8636A EPF8820	208-Pin RQFP EPF8636A	208-Pin RQFP EPF8820	225-Pin BGA EPF8820
nSP (1)	R15	207	207	A15
MSEL0 (1)	T15	4	4	B14
MSEL1 (1)	T3	49	49	R15
nSTATUS (1)	B3	108	108	P2
nCONFIG (1)	C3	103	103	R1
DCLK (1)	C15	158	158	B2
CONF_DONE (1)	B15	153	153	A1
nWS	C5	114	114	L4
nRS	B5	66	116	K5
RDCLK	C11	64	137	F1
nCS	B13	116	145	D1
CS	A16	118	148	C1
RDYnBUSY	A8	201	127	J3
CLKUSR	A10	59	134	G2
ADD17	R5	57	43	M14
ADD16	U3	43	42	L12
ADD15	T5	41	41	M15
ADD14	U4	39	40	L13
ADD13	R6	37	39	L14
ADD12	T6	31	35	K13
ADD11	R7	30	33	K15
ADD10	T7	29	31	J13

Table 9. FLEX 8000 192-, 208- & 225-Pin Package Pin-Outs (Part 2 of 3)

Pin Name	192-Pin PGA EPF8636A EPF8820	208-Pin RQFP EPF8636A	208-Pin RQFP EPF8820	225-Pin BGA EPF8820
ADD9	T8	28	29	J15
ADD8	U9	24	25	G14
ADD7	U10	23	23	G13
ADD6	U11	22	21	G11
ADD5	U12	21	19	F14
ADD4	R12	14	14	E13
ADD3	U14	12	13	D15
ADD2	U15	10	11	D14
ADD1	R13	8	10	E12
ADD0	U16	203	9	C15
DATA7	H17	178	178	A7
DATA6	G17	172	176	D7
DATA5	F17	169	174	A6
DATA4	E17	165	172	A5
DATA3	G15	162	171	B5
DATA2	F15	160	167	E6
DATA1	E16	149	165	D5
DATA0	C16	147	162	C4
TDI (2)	R11	72	20	F15
TDO (2)	B9	120	129	J2
TCLK (2)	U8	74	30	J14
TMS (2)	U7	76	32	J12
nTRST (1)	R3	54	54	P14

Table 9. FLEX 8000 192-, 208- & 225-Pin Package Pin-Outs (Part 3 of 3)

Pin Name	192-Pin PGA EPF8636A EPF8820	208-Pin RQFP EPF8636A	208-Pin RQFP EPF8820	225-Pin BGA EPF8820
Dedicated Inputs	A5, U5, U13, A13	7, 45, 112, 150	17, 36, 121, 140	F4, L1, K12, E15
VCCINT (5.0 V)	C8, C9, C10, R8, R9, R10, R14	5, 6, 33, 110, 137,	5, 6, 27, 48, 119, 141	F5, F10, E1, L2, K4, M12, P15, H13, H14, B15, C13
VCCIO (5.0 V or 3.3 V)	D3, D4, D9, D14, D15, G4, G14, L4, L14, P4, P9, P14	32, 55, 78, 91, 102, 138, 159, 182, 193, 206	26, 55, 69, 87, 102, 131, 159, 173, 191, 206	H3, H2, P6, R6, P10, N10, R14, N13, H15, H12, D12, A14, B10, A10, B6, C6, A2, C3, M4, R2
GND	C4, D7, D8, D10, D11, H4, H14, K4, K14, P7, P8, P10, P11	19, 20, 46, 47, 60, 67, 96, 109, 111, 124, 125, 151, 164, 171, 200	15, 16, 37, 38, 60, 78, 96, 109, 110, 120, 130, 142, 152, 164, 182, 200	B1, D4, E14, F7, F8, F9, F12, G6, G7, G8, G9, G10, H1, H4, H5, H6, H7, H8, H9, H10, H11, J6, J7, J8, J9, J10, K6, K7, K8, K9, K11, L15, N3, P1
No Connect (N.C.)	C6, C12, C13, C14, E3, E15, F3, J3, J4, J14, J15, N3, N15, P3, P15, R4 (3)	1, 2, 3, 16, 17, 18, 25, 26, 27, 34, 35, 36, 50, 51, 52, 53, 104, 105, 106, 107, 121, 122, 123, 130, 131, 132, 139, 140, 141, 154, 155, 156, 157, 208	1, 2, 3, 50, 51, 52, 53, 104, 105, 106, 107, 154, 155, 156, 157, 208	–
Total User I/O Pins	132 (4)	132	148	148

Notes to Table 9:

- (1) Dedicated pin (not available as a user I/O pin).
- (2) Available as a user I/O pin if device is not configured to use JTAG BST circuitry.
- (3) These pins are No Connect pins only for EPF8636A devices, not for EPF8820 devices.
- (4) The EPF8636A device has 132 user I/O pins; the EPF8820 device has 148 user I/O pins.

Table 10. FLEX 8000 232-, 240-, 280 & 304-Pin Package Pin-Outs (Part 1 of 3)

Pin Name	232-Pin PGA EPF81188 EPF81188A	240-Pin QFP EPF81188 EPF81188A	280-Pin PGA EPF85100	304-Pin RQFP EPF81500
nSP (1)	C14	237	W1	304
MSEL0 (1)	G15	21	N1	26
MSEL1 (1)	L15	40	H3	51
nSTATUS (1)	L3	141	G19	178
nCONFIG (1)	R4	117	B18	152
CONF_DONE (1)	G3	160	M16	204
DCLK (1)	C4	184	U18	230
nWS	P1	133	F18	167
nRS	N1	137	G18	171
RDCLK	G2	158	M17	202
nCS	E2	166	N16	212
CS	E3	169	N18	215
RDYnBUSY	K2	146	J17	183
CLKUSR	H2	155	K19	199
ADD17	R15	58	E3	73
ADD16	T17	56	E2	71
ADD15	P15	54	F4	69
ADD14	M14	47	G1	60
ADD13	M15	45	H2	58
ADD12	M16	43	H1	56
ADD11	K15	36	J3	47
ADD10	K17	34	K3	45
ADD9	J14	32	K4	43
ADD8	J15	29	L1	34
ADD7	H17	27	L2	32
ADD6	H15	25	M1	30
ADD5	F16	18	N2	20
ADD4	F15	16	N3	18
ADD3	F14	14	N4	16
ADD2	D15	7	U1	8
ADD1	B17	5	U2	6
ADD0	C15	3	V1	4

Table 10. FLEX 8000 232-, 240-, 280 & 304-Pin Package Pin-Outs (Part 2 of 3)

Pin Name	232-Pin PGA EPF81188 EPF81188A	240-Pin QFP EPF81188 EPF81188A	280-Pin PGA EPF81500	304-Pin RQFP EPF81500
DATA7	A7	205	W13	254
DATA6	D8	203	W14	252
DATA5	B7	200	W15	250
DATA4	C7	198	W16	248
DATA3	D7	196	W17	246
DATA2	B5	194	V16	243
DATA1	A3	191	U16	241
DATA0	A2	189	V17	239
TDI (2)	–	–	B1	80
TDO (2)	–	–	C17	149
TCLK (2)	–	–	A19	148
TMS (2)	–	–	C2	81
nTRST (2)	–	–	A18	145

Table 10. FLEX 8000 232-, 240-, 280 & 304-Pin Package Pin-Outs (Part 3 of 3)

Pin Name	232-Pin PGA EPF81188 EPF81188A	240-Pin QFP EPF81188 EPF81188A	280-Pin PGA EPF81500	304-Pin RQFP EPF81500
Dedicated Inputs	C1, C17, R1, R17	10, 51, 130, 171	F1, F16, P3, P19	12, 64, 164, 217
VCCINT (5.0 V)	E4, H4, L4, P12, L14, H14, E14, R14, U1	20, 42, 64, 66, 114, 128, 150, 172, 236	B17, D3, D15, E8, E10, E12, E14, R7, R9, R11, R13, R14, T14	24, 54, 77, 144, 79, 115, 162, 191, 218, 266, 301
VCCIO (5.0 V or 3.3 V)	N10, M13, M5, K13, K5, H13, H5, F5, E10, E8, N8, F13	19, 41, 65, 81, 99, 116, 140, 162, 186, 202, 220, 235	D14, E7, E9, E11, E13, R6, R8, R10, R12, T13, T15	22, 53, 78, 99, 119, 137, 163, 193, 220, 244, 262, 282, 300
GND	A1, D6, E11, E7, E9, G4, G5, G13, G14, J5, J13, K4, K14, L5, L13, N4, N7, N9, N11, N14	8, 9, 30, 31, 52, 53, 72, 90, 108, 115, 129, 139, 151, 161, 173, 185, 187, 193, 211, 229	D4, D5, D16, E4, E5, E6, E15, E16, F5, F15, G5, G15, H5, H15, J5, J15, K5, K15, L5, L15, M5, M15, N5, N15, P4, P5, P15, P16, R4, R5, R15, R16, T4, T5, T16,	9, 11, 36, 38, 65, 67, 90, 108, 116, 128, 150, 151, 175, 177, 206, 208, 231, 232, 237, 253, 265, 273, 291
No Connect (N.C.)	—	61, 62, 119, 120, 181, 182, 239, 240		10, 21, 23, 25, 35, 37, 39, 40, 41, 42, 52, 55, 66, 68, 146, 147, 161, 173, 174, 176, 187, 188, 189, 190, 192, 194, 195, 205, 207, 219, 221, 233, 234, 235, 236, 302, 303
Total User I/O Pins	180	180	204	204

Notes to Table 10:

- (1) Dedicated pin (not available as a user I/O pin).
- (2) Dedicated JTAG pin (not available as a user I/O pin).

Package Outlines

Figures 21 through 31 show the package outlines for all FLEX 8000 devices. Package outlines are listed here in ascending pin count order. Maximum lead coplanarity is 0.004 in. (0.10 mm). For information on device package ordering codes, see *Ordering Information* in the current data book. Package outline dimensions are shown in the following formats:

min. inches (min. millimeters)

max. inches (max. millimeters)

or:

nominal inches ± tolerance
(nominal millimeters ± tolerance)

or:

inches
(millimeters) BSC, Min., Max., Ref., Typ.

Figure 21. 84-Pin Plastic J-Lead Chip Carrier (PLCC)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in inches.

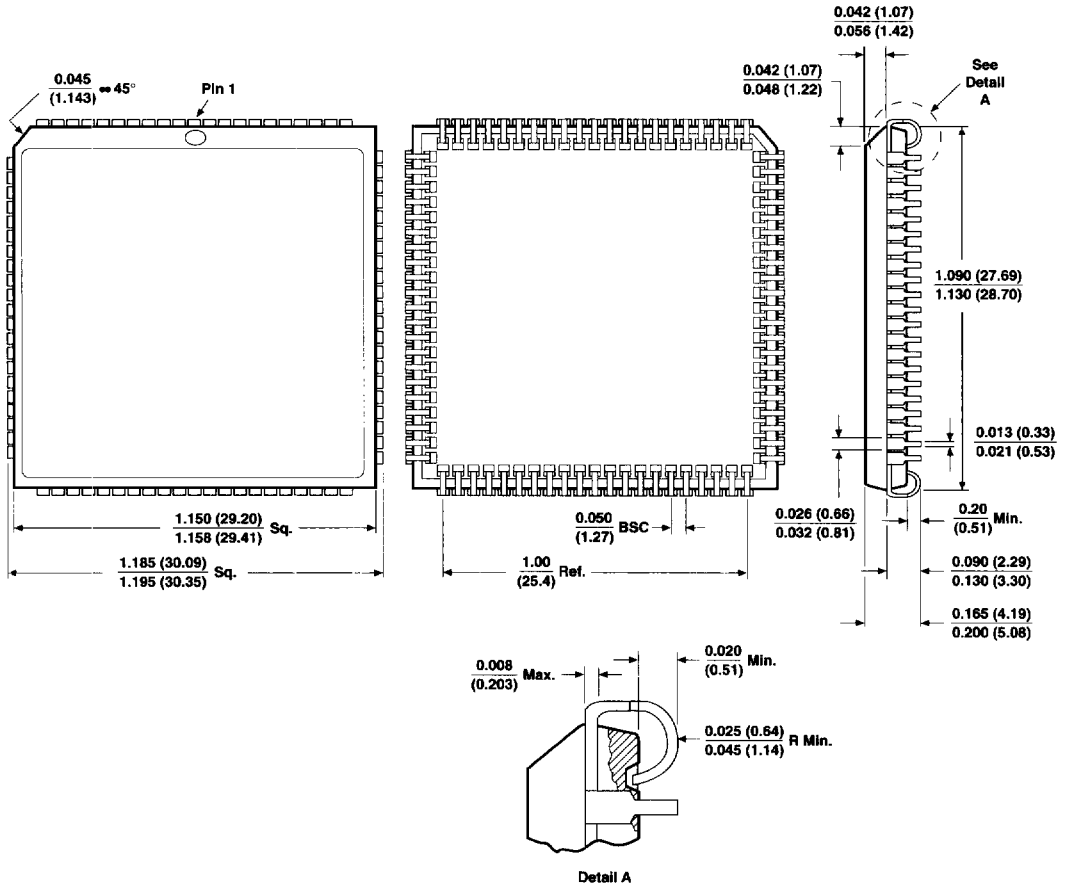


Figure 22. 100-Pin Thin Plastic Quad Flat Pack (TQFP)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.

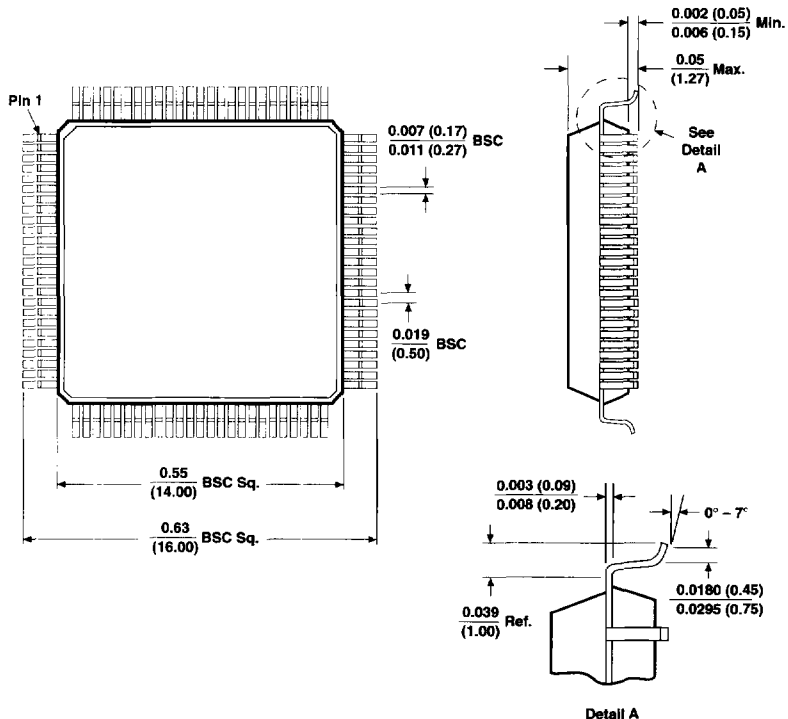


Figure 23. 160-Pin Ceramic Pin-Grid Array (PGA)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in inches.

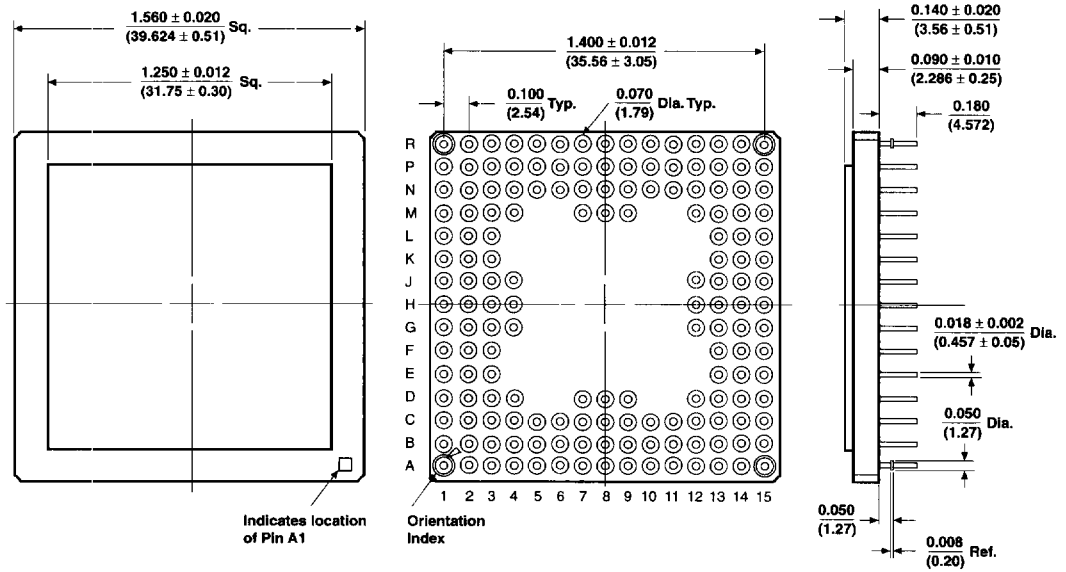


Figure 24. 160-Pin Plastic Quad Flat Pack (PQFP)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.

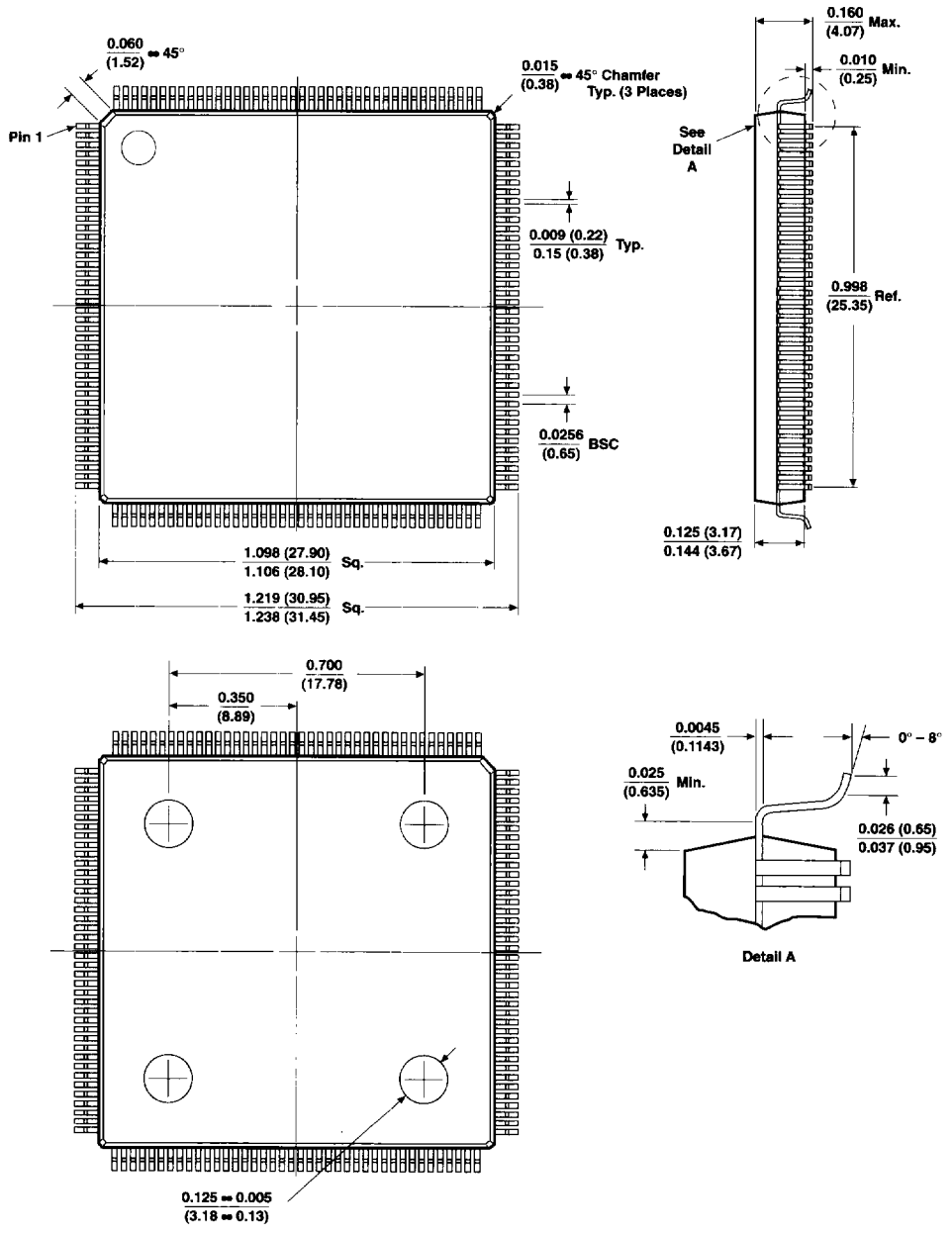


Figure 25. 192-Pin Ceramic Pin-Grid Array (PGA)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in inches.

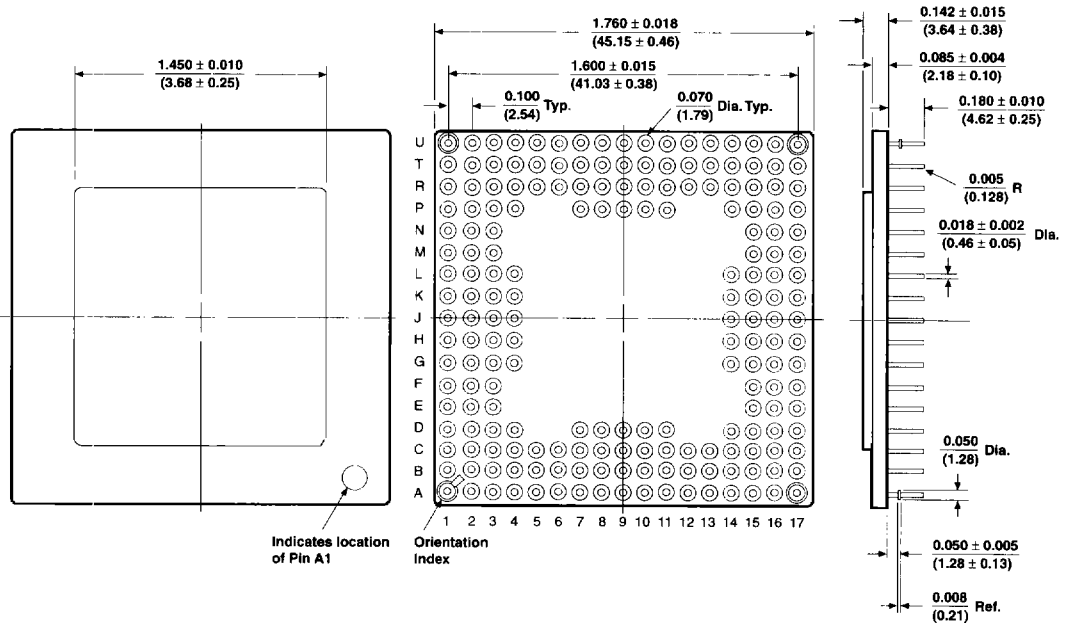


Figure 26. 208-Pin Power Quad Flat Pack (RQFP)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.

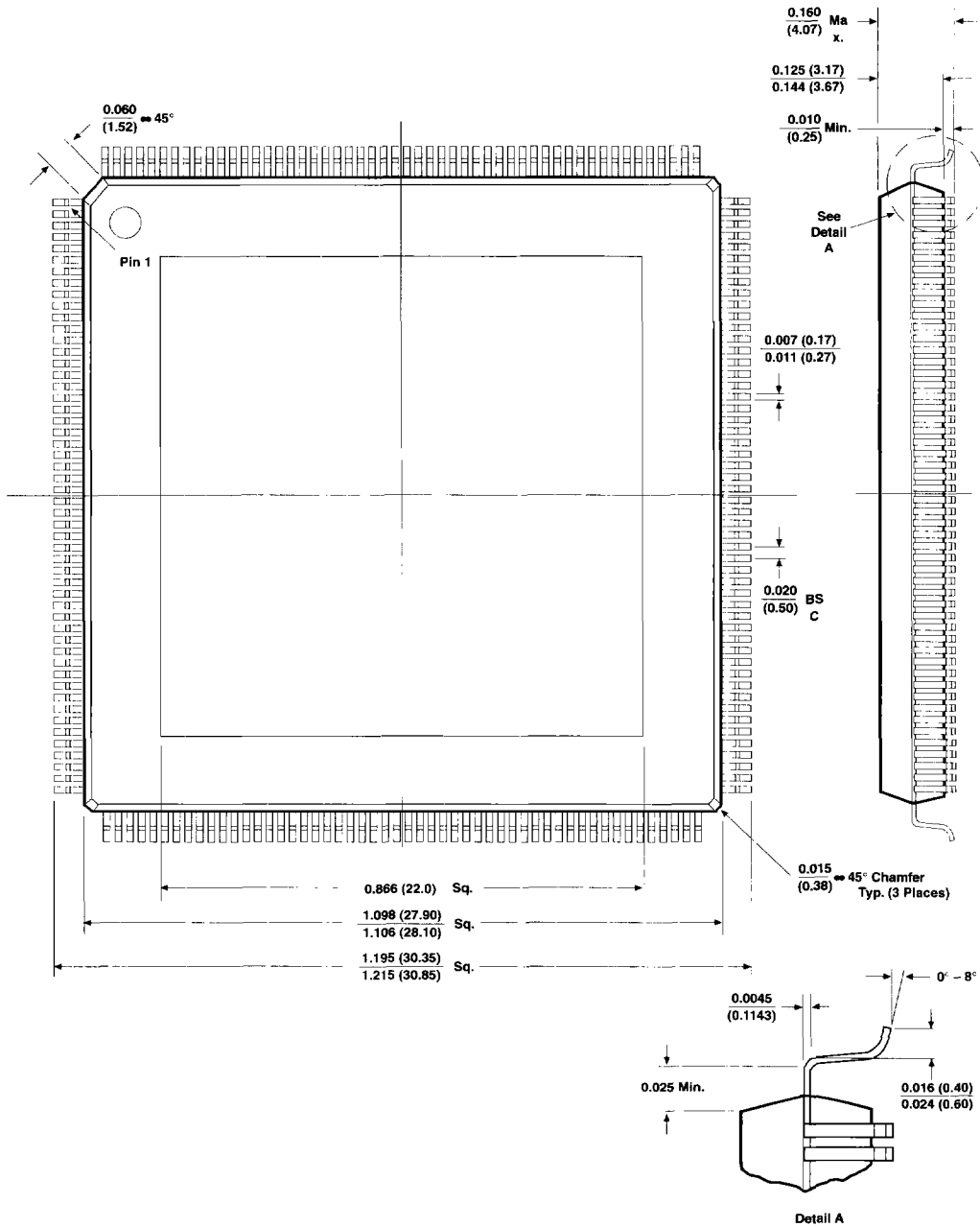


Figure 27. 225-Pin Ball-Grid Array (BGA)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.

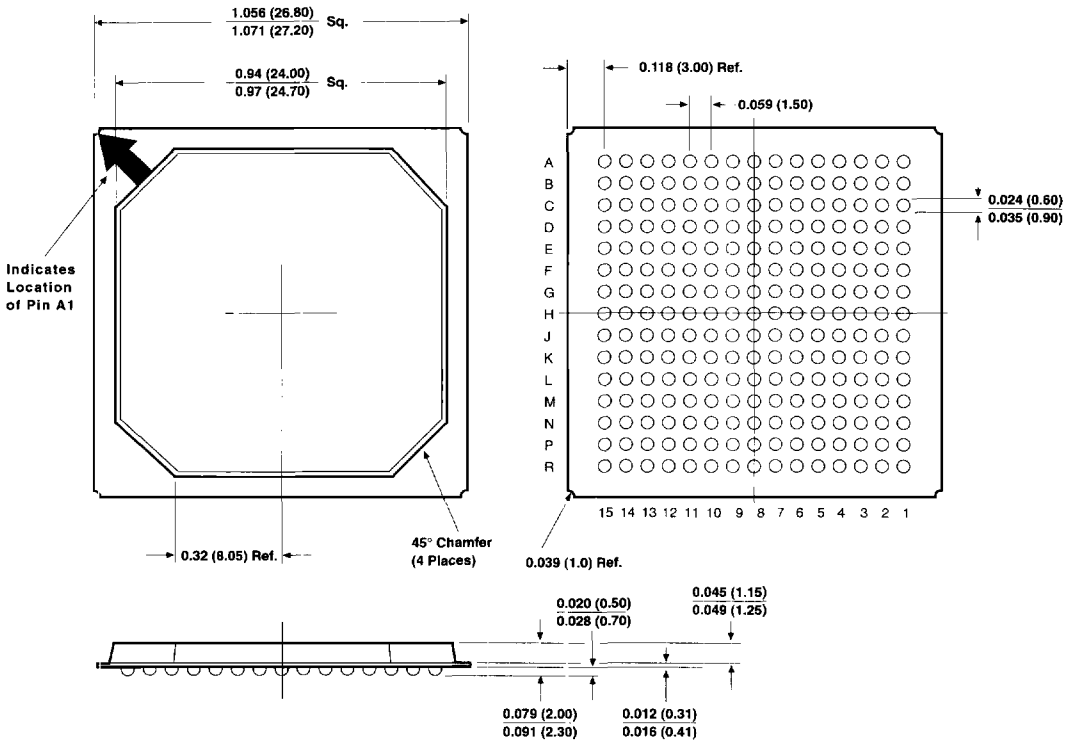


Figure 28. 232-Pin Ceramic Pin-Grid Array (PGA)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in inches.

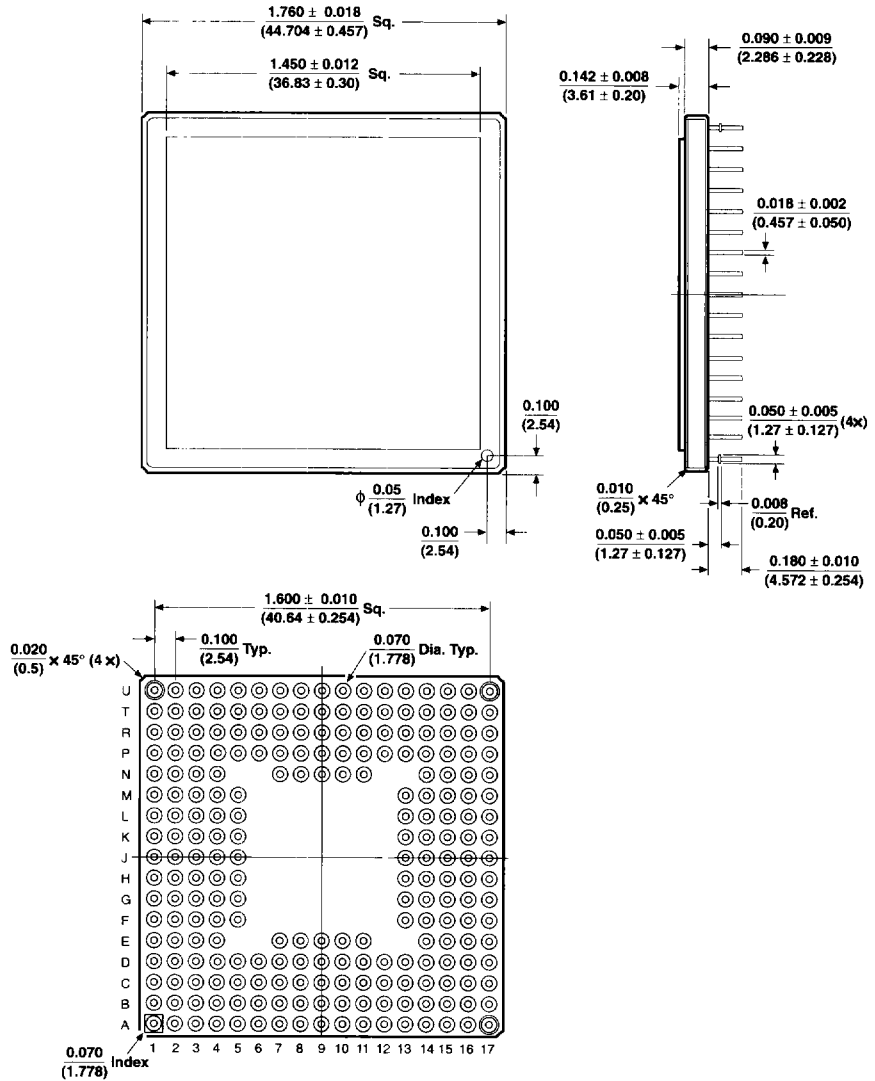


Figure 29. 240-Pin Power Quad Flat Pack (RQFP)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.

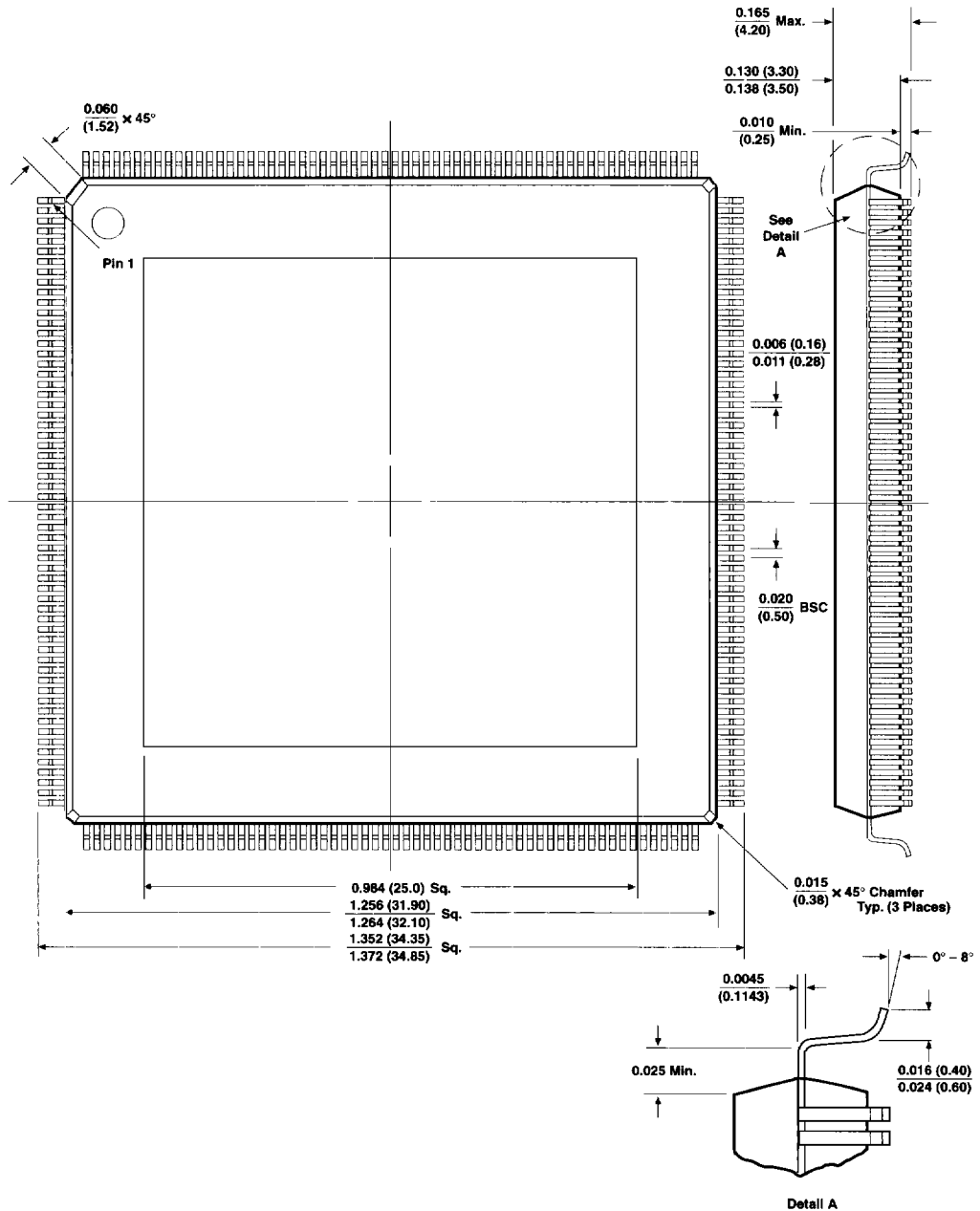


Figure 30. 280-Pin Pin-Grid Array (PGA)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.

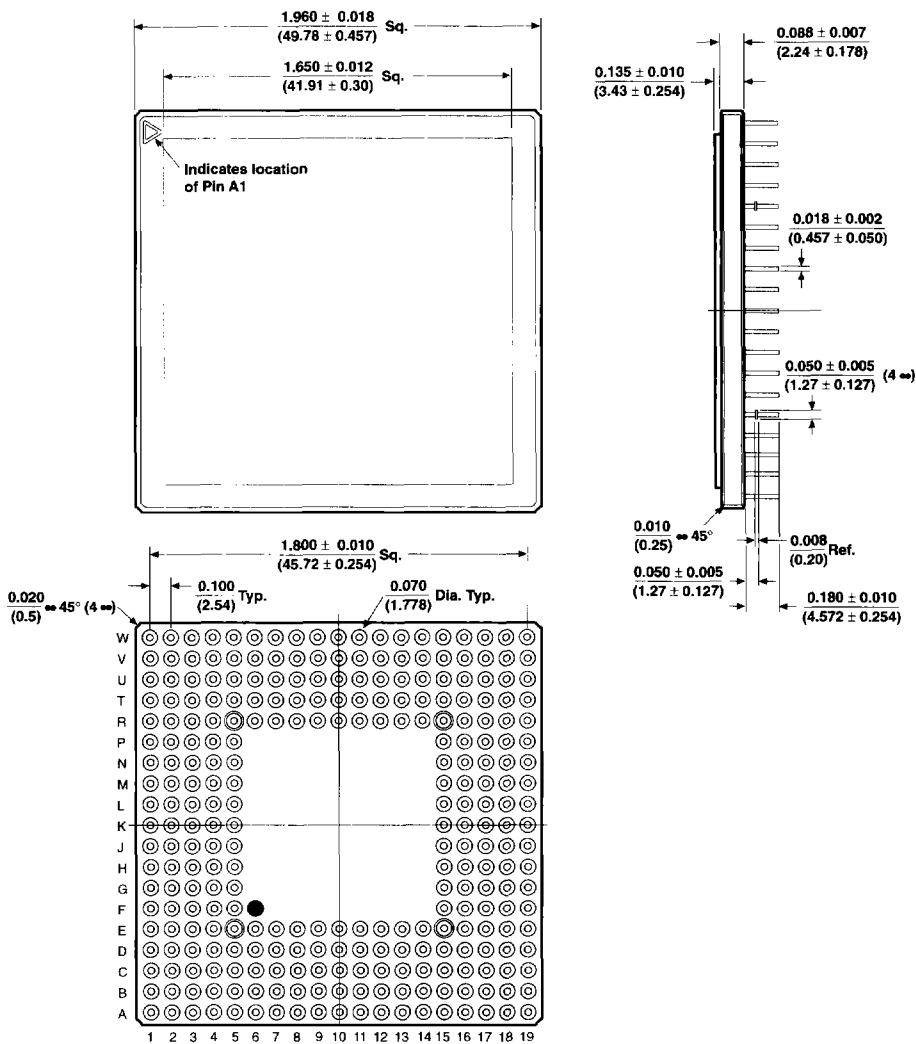
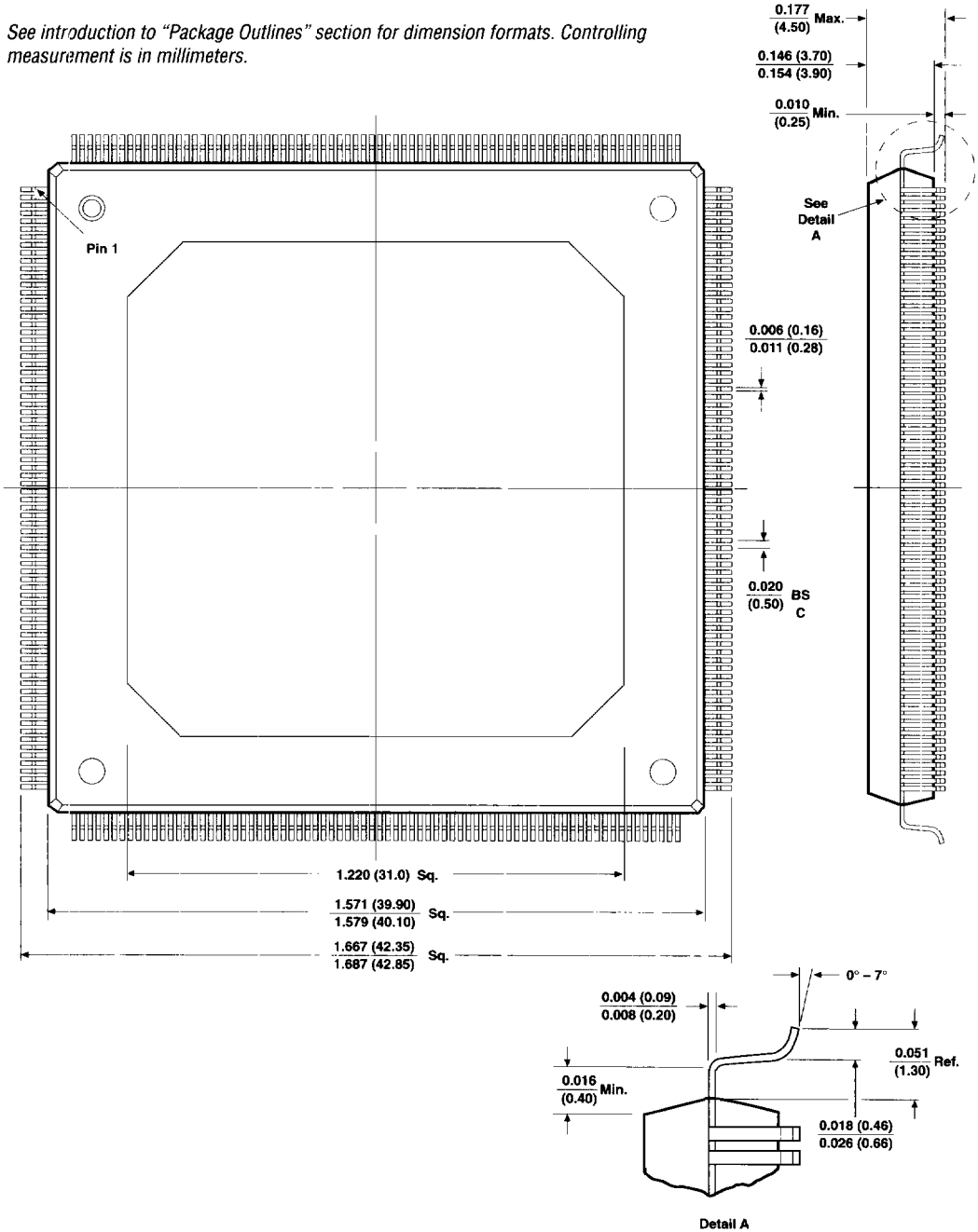


Figure 31. 304-Pin Power Quad Flat Pack (RQFP)

See introduction to "Package Outlines" section for dimension formats. Controlling measurement is in millimeters.





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